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ZL40231

Low Skew, Low Additive Jitter, 10 Output LVPECL/LVDS/ HCSL Fanout Buffer with One LVC MOS Output

Features

- 3-to-1 Input Multiplexer: Two Inputs Accept Any Differential (LVPECL, HCSL, LVDS, SSTL, CML, LVC MOS) or a Single-Ended Signal and the Third Input Accepts a Crystal or a Single-Ended Signal
- Ten Differential LVPECL/LVDS/HCSL Outputs
- One LVC MOS Output
- Ultra-Low Additive Jitter: 24 fs (Integration Band: 12 kHz to 20 MHz at 625 MHz Clock Frequency)
- Supports Clock Frequencies from 0 to 1.6 GHz
- Supports 2.5V or 3.3V Power Supplies on LVPECL/LVDS/HCSL Outputs
- Supports 1.5V, 1.8V, 2.5V, or 3.3V on LVC MOS Output
- Embedded Low Dropout (LDO) Voltage Regulator Provides Superior Power Supply Noise Rejection
- Maximum Output to Output Skew of 40 ps
- Device Controlled via Control Pins

Applications

- PCIe Gen1/2/3/4/5/6 Clock Distribution
- Low-Jitter Clock Trees
- Logic Translation
- Clock and Data Signal Restoration
- Wired Communications: OTN, SONET/SDH, GE, 10GE, FC and 10G FC
- General Purpose Clock Distribution
- Wireless Communications
- High Performance Microprocessor Clock Distribution
- Test Equipment

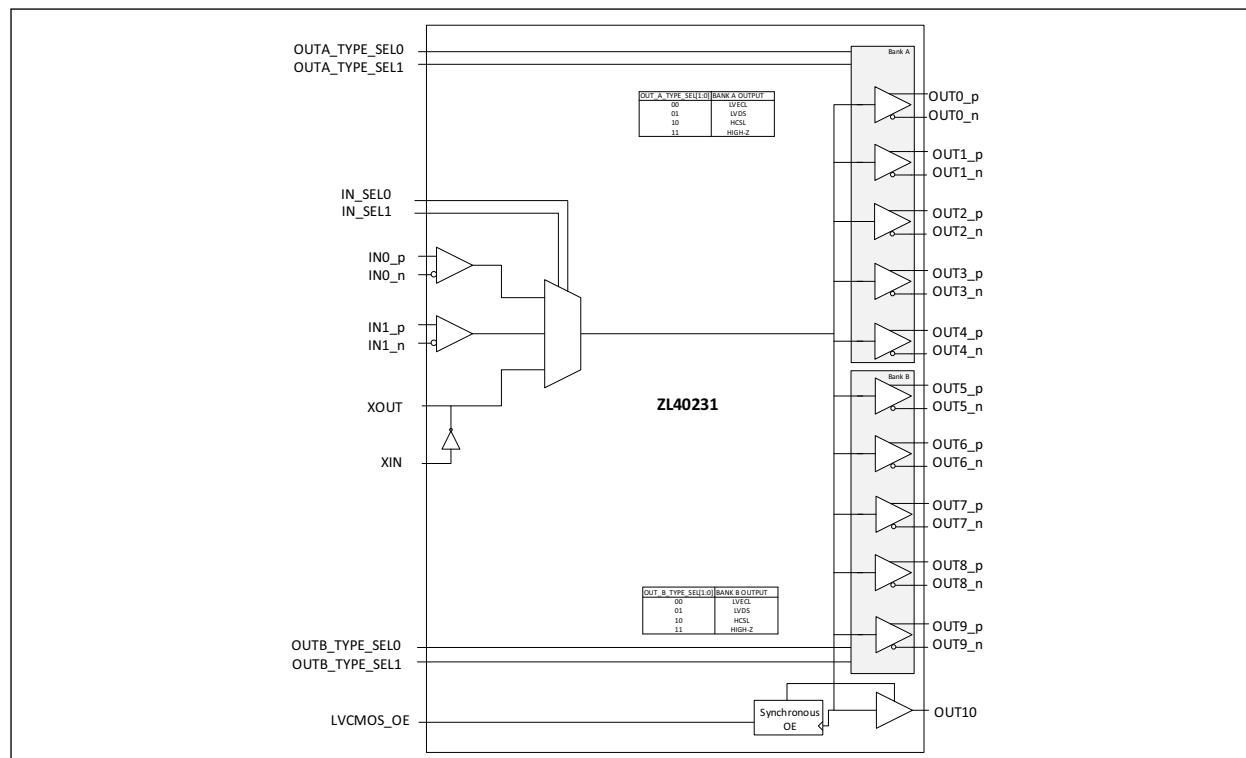


FIGURE 0-1: Functional Block Diagram.

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1.0 PIN DESCRIPTION AND CONFIGURATION

The ZL40231 is packaged in a 7 mm x 7 mm, 48-lead VQFN.

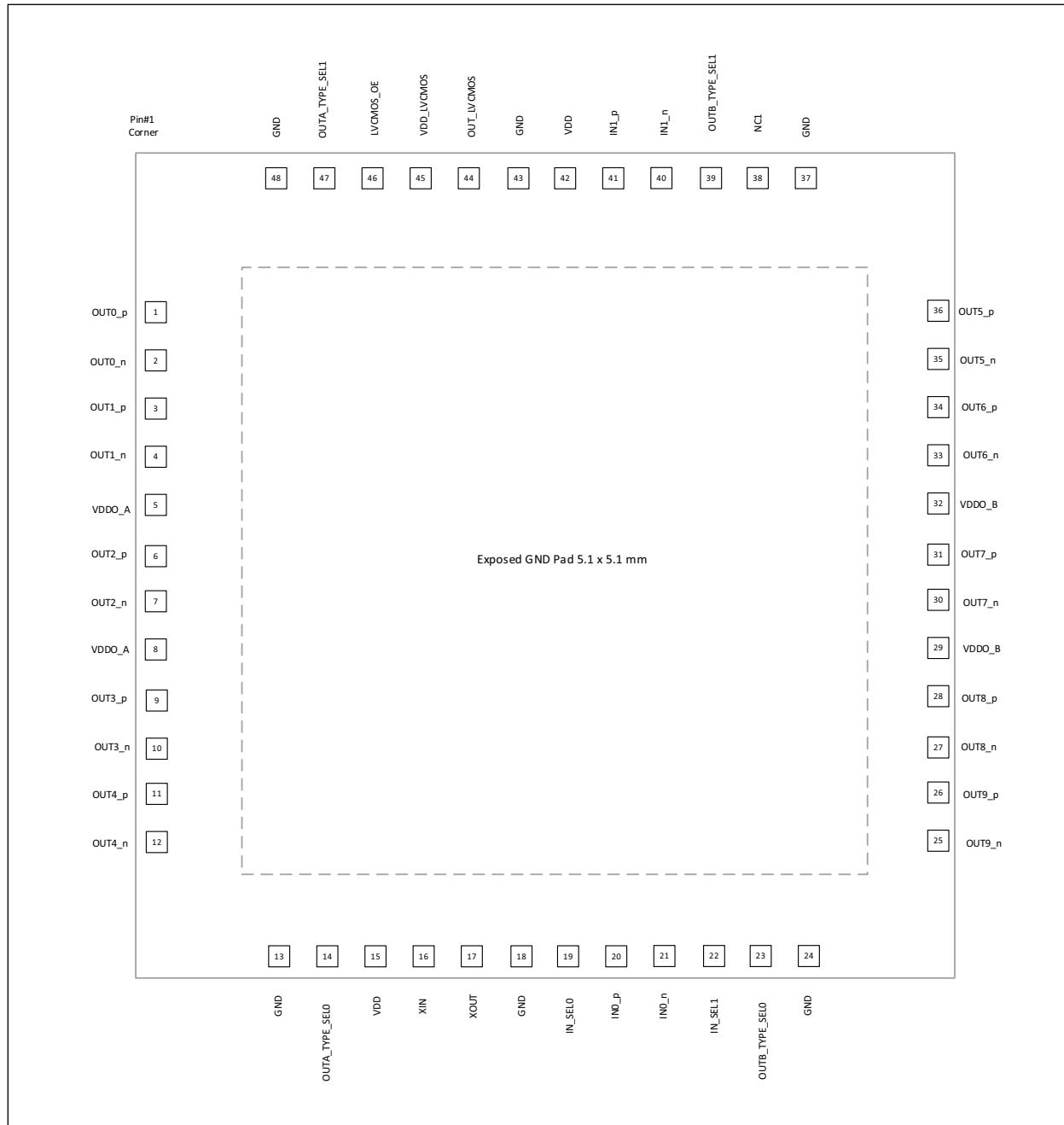


FIGURE 1-1: 48-Lead 7 mm x 7 mm VQFN.

1.1 Pin Descriptions

All device inputs and outputs are LVPECL unless described otherwise. The I/O column uses the following symbols: I – input, I_{PU} – input with 300 kΩ internal pull-up resistor, I_{PD} – input with 300 kΩ internal pull-down resistor, I_{APU} – input with 31 kΩ internal pull-up resistor, I_{APD} – input with 30 kΩ internal pull-down resistor, $I_{APU/APD}$ – input biased to $V_{DD}/2$ with 60 kΩ internal pull-up and pull-down resistors (30 kΩ equivalent), O – output, I/O – Input/Output pin, NC – No connect, P – power supply pin.

TABLE 1-1: PIN DESCRIPTION

| Pin Number | Pin Name | Type | Description |
|------------------------|------------|---------------|---|
| Input Reference | | | |
| 20 | IN0_p | I_{APD} | Input Differential or Single-Ended References 0 and 1 Input frequency range 0 Hz to 1.6 GHz. Non-inverting inputs (_p) are pulled down with internal 30 kΩ pull-down resistors. Inverting inputs (_n) are pulled up and pulled down with 60 kΩ internal resistors (30 kΩ equivalent) to keep inverting input voltages at $V_{DD}/2$ when inverting inputs are left floating (device fed with a single-ended reference). |
| 21 | IN0_n | $I_{APU/APD}$ | |
| 41 | IN1_p | I_{APD} | |
| 40 | IN1_n | $I_{APU/APD}$ | |
| Output Clocks | | | |
| 1 | OUT0_p | O | Ultra-Low Additive Jitter Differential LVPECL/HCSL/LVDS Outputs 0 to 9 Output frequency range 0 Hz to 1.6 GHz Type (LVPECL/HCSL/LVDS/High-Z) of each output bank is controlled via OUTA/B_TYPE_SEL0/1 pins. |
| 2 | OUT0_n | | |
| 3 | OUT1_p | | |
| 4 | OUT1_n | | |
| 6 | OUT2_p | | |
| 7 | OUT2_n | | |
| 9 | OUT3_p | | |
| 10 | OUT3_n | | |
| 11 | OUT4_p | | |
| 12 | OUT4_n | | |
| 36 | OUT5_p | | |
| 35 | OUT5_n | | |
| 34 | OUT6_p | | |
| 33 | OUT6_n | | |
| 31 | OUT7_p | | |
| 30 | OUT7_n | | |
| 28 | OUT8_p | | |
| 27 | OUT8_n | | |
| 26 | OUT9_p | | |
| 25 | OUT9_n | | |
| 44 | OUT_LVCMOS | O | Ultra-Low Additive Jitter LVCMOS Output 0 to 9 Output frequency range 0 Hz to 250 MHz |

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TABLE 1-1: PIN DESCRIPTION (CONTINUED)

| Pin Number | Pin Name | Type | Description | | |
|---------------------------|----------------------------------|--|---|-----------------------|----------------------|
| Control | | | | | |
| 19 22 | IN_SEL0 IN_SEL1 | I _{PD} or I _{PU} | Input select pins. Logic level on these pins selects which input will be passed to the output. | | |
| | | | IN_SEL1 | IN_SEL0 | OUTN |
| | | | 0 | 0 | Input 0 (IN0) |
| | | | 0 | 1 | Input 1 (IN1) |
| | | | 1 | X | Crystal Oscillator |
| 14 47 | OUTA_TYPE_SEL0 OUTA_TYPE_SEL1 | I _{PD} | Output Signal for Bank A: Selects Type of the output for Bank A (Outputs 0 to 4). | | |
| | | | OUTA_TYPE_SEL1 | OUTA_TYPE_SEL0 | Output 0 to 4 |
| | | | 0 | 0 | LVPECL |
| | | | 0 | 1 | LVDS |
| | | | 1 | 0 | HCSL |
| | | | 1 | 1 | High-Z (Disabled) |
| 23 39 | OUTB_TYPE_SEL0 OUTB_TYPE_SEL1 | I _{PD} | Output Signal for Bank B: Selects Type of the output for Bank B (Outputs 5 to 9). | | |
| | | | OUTB_TYPE_SEL1 | OUTB_TYPE_SEL0 | Output 5 to 9 |
| | | | 0 | 0 | LVPECL |
| | | | 0 | 1 | LVDS |
| | | | 1 | 0 | HCSL |
| | | | 1 | 1 | High-Z (Disabled) |
| 46 | LVCMOS_OE | I | Output enable for LVCMOS outputs: When high LVCMOS output is enabled. When low LVCMOS output is High-Z | | |
| Crystal Oscillator | | | | | |
| 16 | XIN | I | Crystal Oscillator Input or Crystal Bypass Mode or Crystal Overdrive Mode If crystal oscillator circuit is not used, connect a pull-down to this pin or connect it to ground. | | |
| 17 | XOUT | O | Crystal Oscillator Output | | |
| No Connect | | | | | |
| 38 | NC1 | NC | No Connect (not connected to the die) Leave unconnected or connect to GND for mechanical support. | | |

TABLE 1-1: PIN DESCRIPTION (CONTINUED)

| Pin Number | Pin Name | Type | Description |
|----------------------------------|------------|------|---|
| Power and Ground | | | |
| 15 42 | VDD | P | Positive Supply Voltage. Connect to 3.3V or 2.5V supply. |
| 5 8 | VDDO_A | P | Positive Supply Voltage for Differential Outputs Bank A Connect to 3.3V or 2.5V power supply. VDDO_A does not have to be connected to the same voltage level as VDD or VDDO_B. These pins power up differential outputs OUT[0:4]_p/n. |
| 29 32 | VDDO_B | P | Positive Supply Voltage for Differential Outputs Bank B Connect to 3.3V or 2.5V power supply. VDDO_B does not have to be connected to the same voltage level as VDD or VDDO_A. These pins power up differential outputs OUT[5:9]_p/n. |
| 45 | VDD_LVCMOS | P | Power Supply Voltage for LVCMOS Output Connect to 3.3V, 2.5V, 1.8V, or 1.5V power supply. |
| 13 18 24 43 37 48 | GND | P | Ground. Connect to ground. |
| ePad | GND | P | Ground. Connect to ground. |

ZL40231

NOTES:

2.0 FUNCTIONAL DESCRIPTION

The ZL40231 is a low additive jitter, low power 3 x 10 LVPECL/HCSL/LVDS fanout buffer.

Two inputs can accept signal in differential (LVPECL, SSTL, LVDS, HSTL, CML) or single-ended (LVPECL or LVCMS) format and the third input can accept a single-ended signal or it can be used to build a crystal oscillator by connecting an external crystal resonator between its XIN and XOUT pins.

The ZL40231 has ten LVPECL/HCSL/LVDS outputs that can be powered from 3.3V or 2.5V supply. Each output bank (A and B) can be independently set to be LVPECL, HCSL, LVDS, or Hi-Z via control OUTA/B_TYPE_SEL0/1 pins.

The device operates from $2.5V \pm 5\%$ or $3.3V \pm 5\%$ supply. Its operation is ensured over the industrial temperature range of -40°C to $+85^{\circ}\text{C}$.

2.1 Clock Inputs

The following blocks diagram shows how to terminate different signals fed to the ZL40231 inputs.

Figure 2-1 shows how to terminate a single ended output such as LVCMS. Resistors Ideally, resistors R1 and R2 should be 100Ω each and $R_o + R_s$ should be 50Ω so that the transmission line is terminated at both ends with characteristic impedance. If the driving strength of the output driver is not sufficient to drive low impedance, the value of series resistor R_s should be increased. This will reduce the voltage swing at the input but this should be fine as long as the input voltage swing requirement is not violated (**Table 4-4**). The source resistors of $R_s = 270\Omega$ could be used for standard LVCMS driver. This will provide 516 mV of voltage swing for 3.3V LVCMS driver with load current of $(3.3V/2) \times (1/(270\Omega + 50\Omega)) = 5.16\text{ mA}$.

For optimum performance both differential input pins (_p and _n) need to be DC biased to the same voltage. Hence, the ratio $R1/R2$ should be equal to the ratio $R3/R4$.

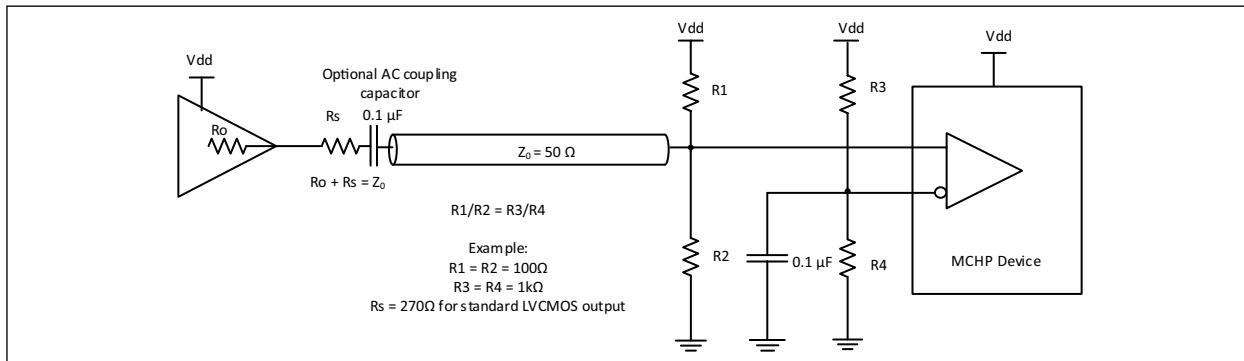


FIGURE 2-1: Input Driven by a Single-Ended Output.

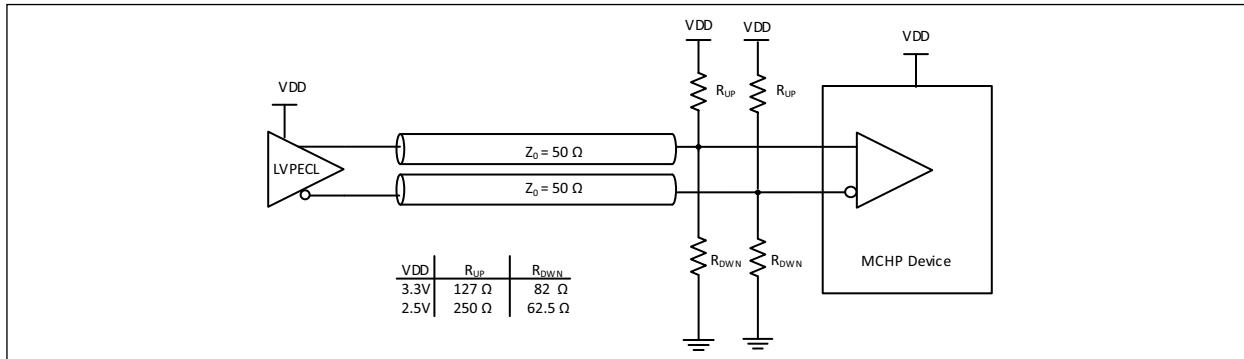


FIGURE 2-2: Input Driven by DC-Coupled LVPECL Output.

ZL40231

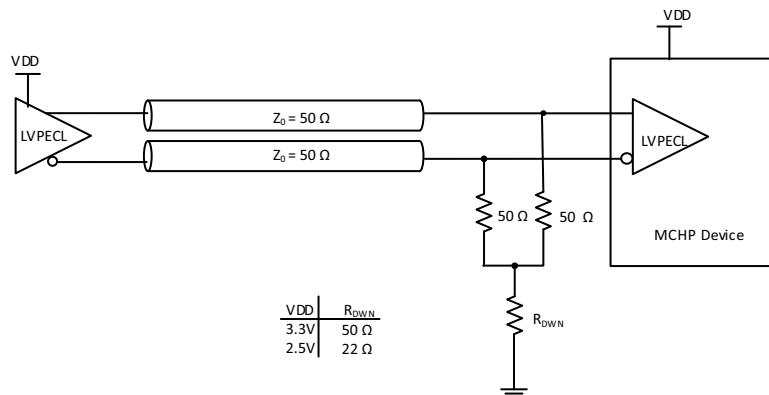


FIGURE 2-3: Input Driven by DC-Coupled LVPECL Output (Alternative Termination).

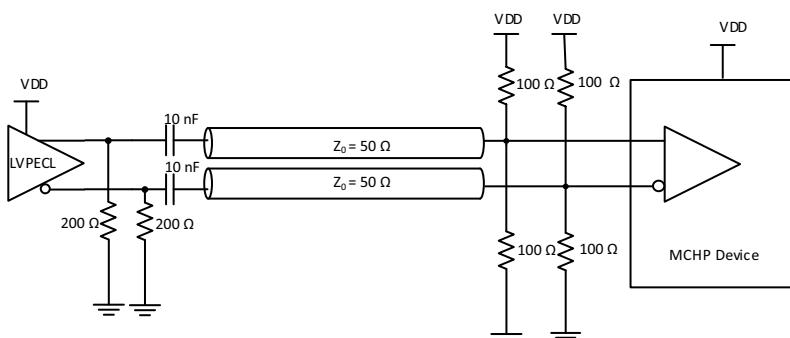


FIGURE 2-4: Input Driven by AC-Coupled LVPECL Output.

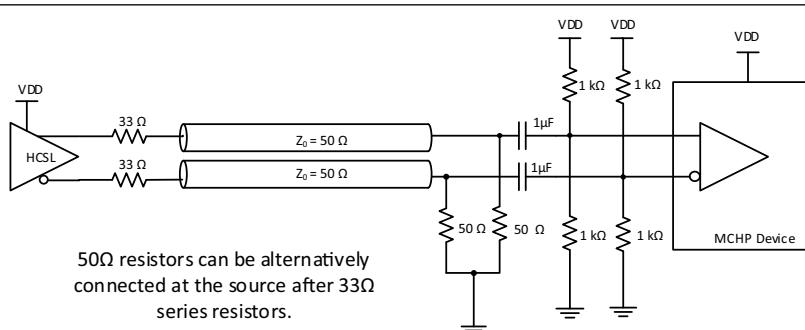


FIGURE 2-5: Input Driven by HCSL Output.

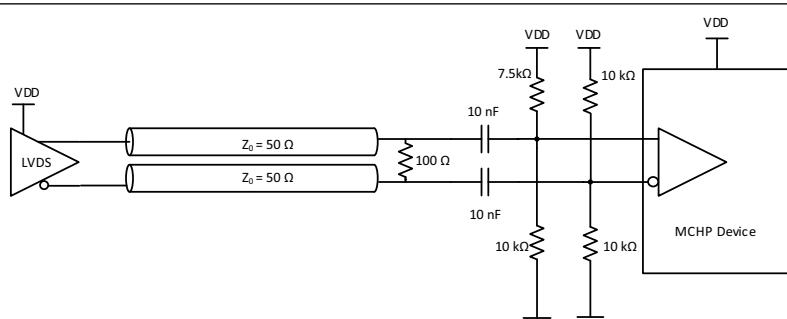


FIGURE 2-6: Input Driven by LVDS Output.

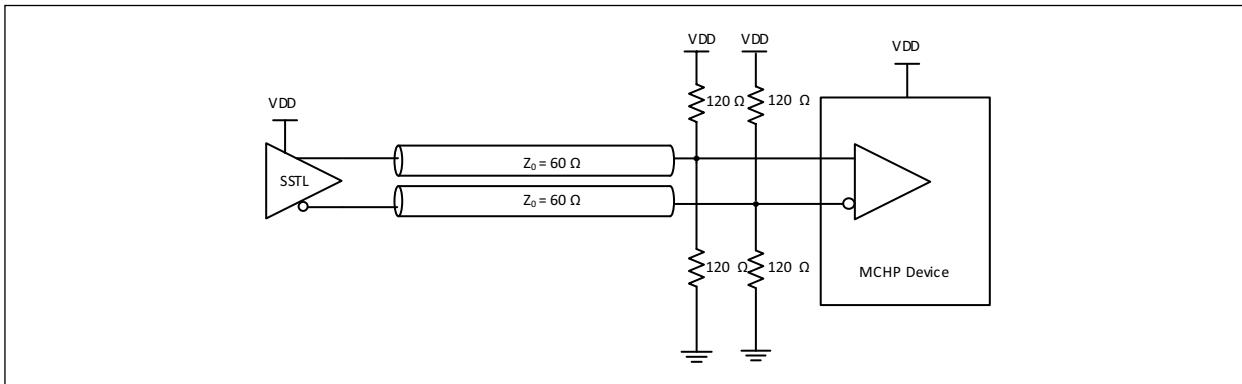


FIGURE 2-7: Input Driven by an SSTL Output.

2.2 Clock Outputs

The LVCMS output (OUT10) requires only a series termination resistor whose value is dependent on the LVCMS output voltage as shown in [Figure 2-8](#).

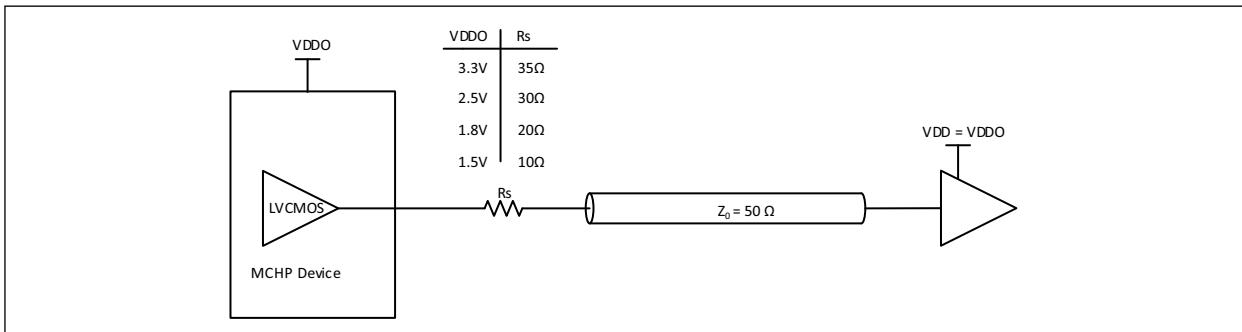


FIGURE 2-8: Termination for LVCMS Output.

Differential outputs LVPECL and LVDS should have the same termination as their corresponding outputs described in the previous section. HCSL outputs should be terminated with 33Ω series resistors at the source and 50Ω shunt resistors at the source or at the end on the transmission line. AC coupling and re-biasing is not required at the outputs when driving native HCSL receivers.

The device is designed to drive the differential input of semiconductor devices. In applications that use a transformer to convert from the differential to the single-ended output (for example, driving an oscilloscope 50Ω input), a resistor larger than 10Ω should be added at the center tap of the primary winding to achieve optimum jitter performance as shown in [Figure 2-9](#). This is to provide a nominal common mode impedance of 10Ω or higher, which is typical for differential terminations.

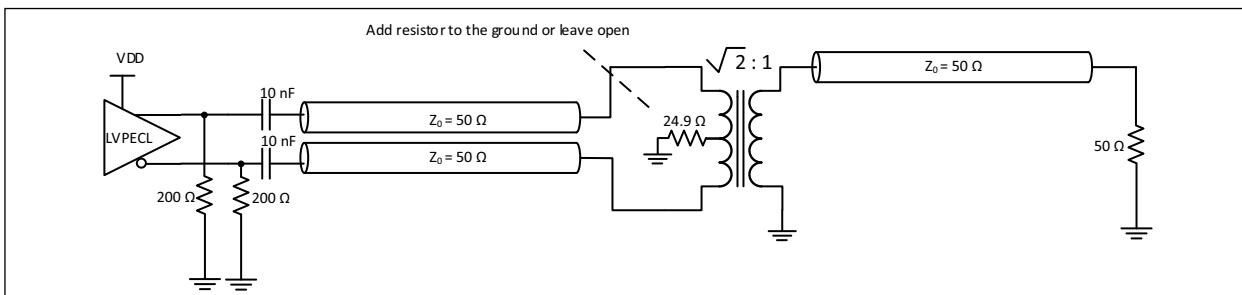


FIGURE 2-9: Driving a Load via Transformer.

2.3 Crystal Oscillator Input

The crystal oscillator circuit can work with crystal resonators from 8 MHz to 60 MHz. Load capacitors C1, C2, and series resistor R_s shall be selected as per crystal vendor recommendation. A shunt resistor is implemented inside the device.

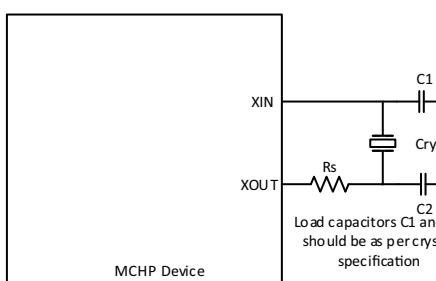


FIGURE 2-10: Crystal Oscillator Circuit.

2.4 Termination of Unused Inputs and Outputs

Unused inputs can be left unconnected or, alternatively, IN_0/1 can be pulled down by a 1 k Ω resistor. Unused outputs should be left unconnected.

2.5 Power Consumption

The device's total power consumption can be calculated as:

EQUATION 2-1:

$$P_T = P_S + P_{XTAL} + P_C + P_{O_DIF} + P_{O_LVCMOS}$$

Where:

$$P_S = V_{DD} \times I_S$$

The core power when the XTAL is not used. The current is specified in [Table 4-3](#). If the XTAL is running, this power should be set to zero.

$$P_{XTAL} = V_{DD} \times I_{DD_XTAL}$$

The core power when the XTAL is used. The current is specified in [Table 4-3](#). If the XTAL is not used, this power should be set to zero.

$$P_C = V_{DDO} \times I_{DD_CM}$$

Common output power shared among all ten outputs.
The current I_{DD_CM} is specified [Table 4-3](#).

$$P_{O_DIF} = V_{DDO} \times (I_{DD_LVDS} \times N_1 + I_{DD_LVPECL} \times N_2 + I_{DD_HCSL} \times N_3)$$

Output power where output current (I_{DD_LVDS}) is specified [Table 4-3](#). For LVPECL or HCSL, just replace I_{DD_LVDS} with I_{DD_LVPECL} or I_{DD_HCSL} . N is the number of enabled differential outputs and can either be 0, 5, or 10.

$$P_{O_LVCMOS} = V_{DD_LVCMOS} \times (I_{DD} \times f / 100MHz + V_{DD_LVCMOS} \times C_{LOAD} \times f)$$

Dynamic LVCMOS output power. I_{DD} is specified in [Table 4-3](#). If LVCMOS output is disabled, this term is equal to zero.

Power dissipated inside the device can be calculated by subtracting the power dissipated in termination/biasing resistors from the power consumption.

EQUATION 2-2:

$$P_D = P_T - N_1 \times P_{LVPECL} - N_2 \times P_{LVDS} - N_3 \times P_{HCSL}$$

Where:

N_1 , N_2 , and N_3 are the number of enabled LVPECL, LVDS, and HSCL outputs, respectively. When both banks are enabled, $N_1 + N_2 + N_3$ equals 10 and one or two of N_1 , N_2 , and N_3 will equal 0.

$$P_{LVPECL} = (V_{OH} - V_B)^2 / 50\Omega + (V_{OL} - V_B)^2 / 50\Omega + (V_{OH} - V_B) \times V_B / 50\Omega + (V_{OL} - V_B) \times V_B / 50\Omega$$

V_{OH} and V_{OL} are the output high and low voltages respectively for LVPECL output.

V_B is LVPECL bias voltage equal to $V_{DD} - 2V$.

$$P_{LVDS} = V_{SW}^2 / 100\Omega \quad V_{SW} \text{ is the voltage swing of the LVDS output.}$$

$$P_{HCSL} = (V_{SW} / 50\Omega)^2 \times (33\Omega + 50\Omega) \quad V_{SW} \text{ is the voltage swing of the HCSL output. } 50\Omega \text{ is the termination resistance and } 33\Omega \text{ is the series resistance of the HCSL output.}$$

2.6 Power Supply Filtering

Each power pin (VDD and VDDO) should be decoupled with a $0.1 \mu F$ capacitor with minimum equivalent series resistance (ESR) and minimum series inductance (ESL). For example, 0402 X5R ceramic capacitors with 6.3V minimum rating could be used. These capacitors should be placed as close as possible to the power pins. To reduce the power noise from adjacent digital components on the board, each power supply could be further insulated with a low resistance ferrite bead with two capacitors. The ferrite bead will also insulate adjacent components from the noise generated by the device. [Figure 2-11](#) shows recommended decoupling for each power pin.

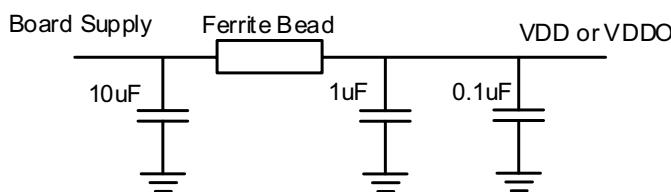


FIGURE 2-11: Power Supply Filtering.

2.7 Power Supplies and Power-Up Sequence

The device has four different power supplies: VDD, VDDO_A, VDDO_B, and VDD_LVC MOS which are mutually independent. Voltages supported by each of these power supplies are specified in [Table 1-1](#).

The device is not sensitive to the power-up sequence. For example, a commonly used sequence where higher voltage comes up before or at the same time as the lower voltages can be used (or any other sequence).

2.8 Host Interface

ZL40231 is controlled via Input Select (IN_SEL0/1) pins that select which one of three inputs is fed to the output and show in [Table 2-1](#) and OUTA/B_TYPE_SEL0/1 pins that select signal level (LVPECL, LVDS, HCSL, or Hi-Z) for each of two (A and B) output banks as shown in [Table 2-2](#).

All input control pins have a low input threshold voltage so they can be driven from the device with low output voltage (FPGA/CPLD). Supported voltages are between 1.2V and V_{DD} (2.5V or 3.3V).

TABLE 2-1: INPUT CLOCK SELECTION

| IN_SEL1 | IN_SEL0 | Selected Input |
|---------|---------|----------------|
| 0 | 0 | IN0_p, IN0_n |
| 0 | 1 | IN1_p, IN1_n |
| 1 | X | XIN |

TABLE 2-2: OUTPUT TYPE SELECTION

| OUTA/B_TYPE_SEL1 | OUTA/B_TYPE_SEL0 | Output |
|------------------|------------------|--------------------------|
| 0 | 0 | LVPECL |
| 0 | 1 | LVDS |
| 1 | 0 | HCSL |
| 1 | 1 | High-Z (Output Disabled) |

3.0 TYPICAL DEVICE PERFORMANCE

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

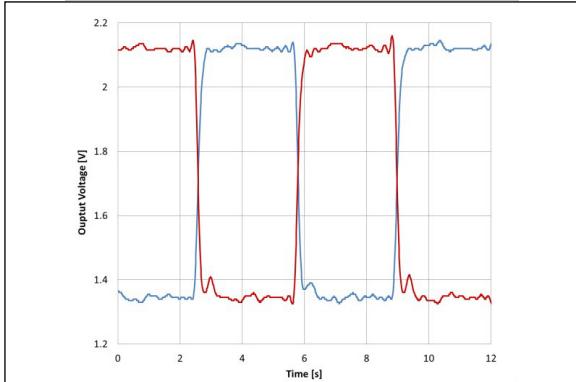


FIGURE 3-1: 156.25 MHz LVPECL.

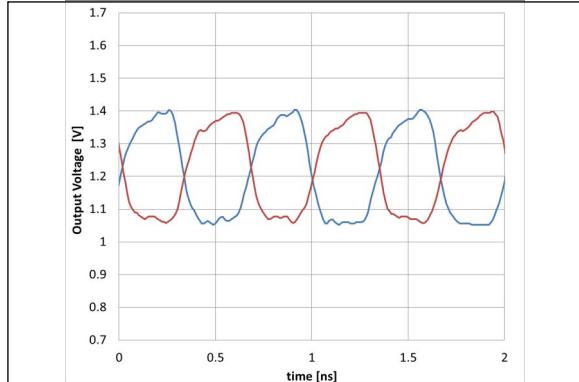


FIGURE 3-4: 1.5 GHz LVDS.

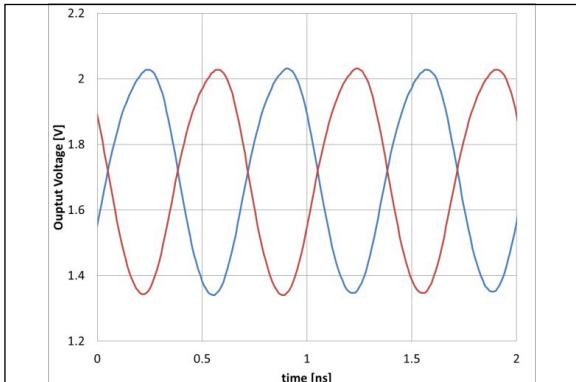


FIGURE 3-2: 1.5 GHz LVPECL.

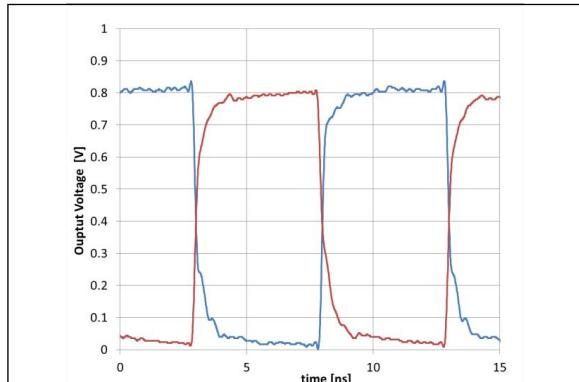


FIGURE 3-5: 100 MHz HCSL.

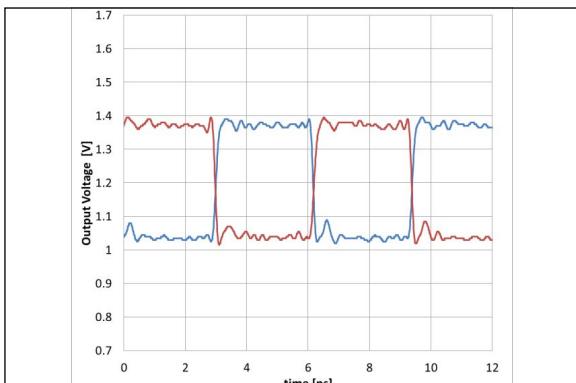


FIGURE 3-3: 156.25 MHz LVDS.

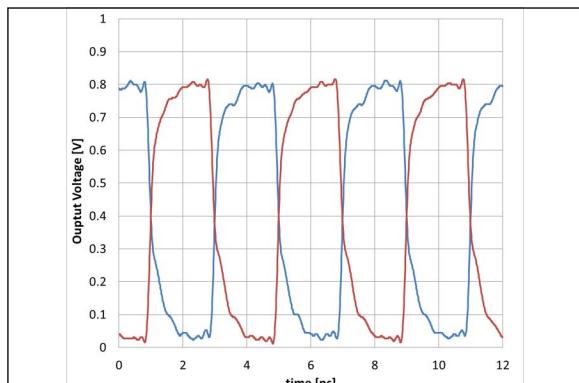


FIGURE 3-6: 250 MHz HCSL.

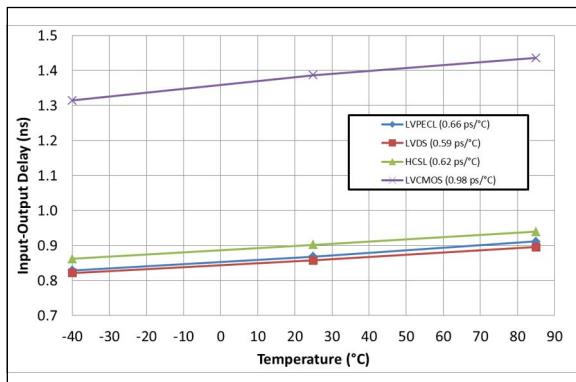


FIGURE 3-7: I/O Delay vs. Temperature.

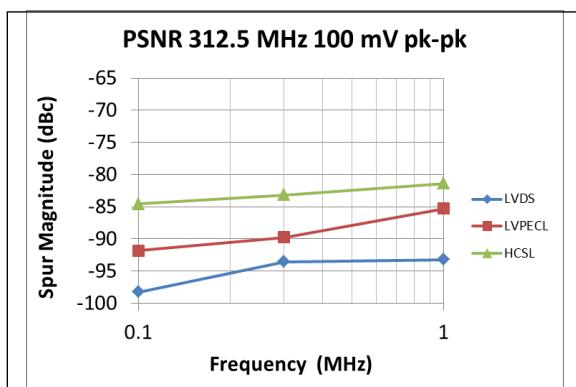


FIGURE 3-8: PSNR vs. Noise Frequency.

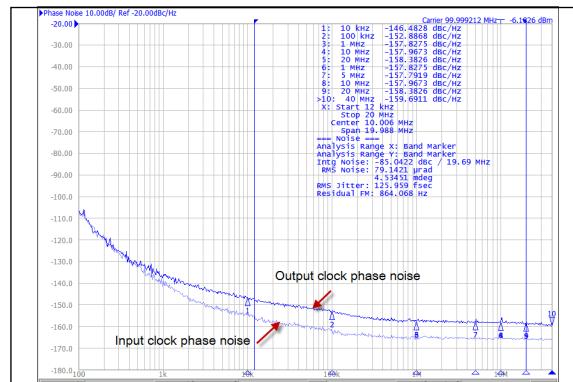


FIGURE 3-10: 100 MHz LVDS Phase Noise.

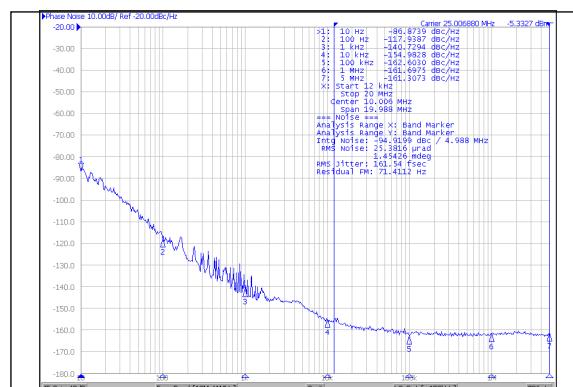


FIGURE 3-11: 25 MHz LVDS Phase Noise in XTAL Mode.

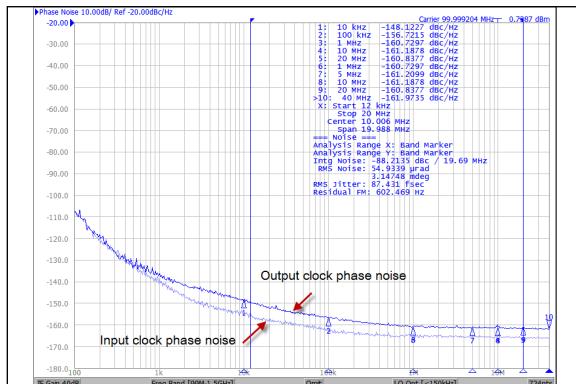


FIGURE 3-9: 100 MHz LVPECL Phase Noise.

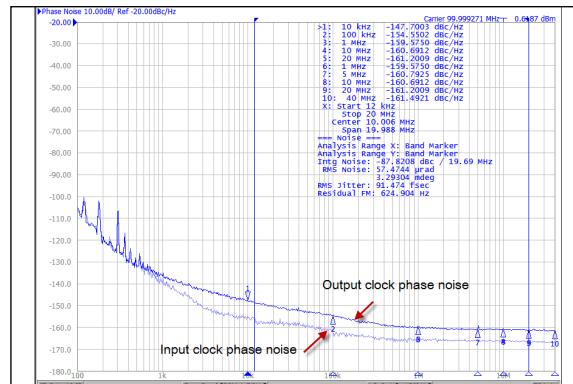


FIGURE 3-12: 100 MHz HCSL Phase Noise.

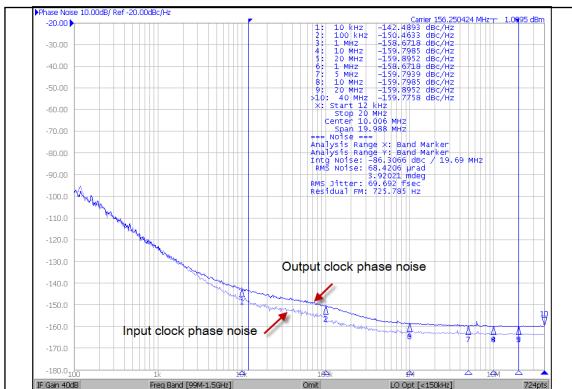


FIGURE 3-13: 156.25 MHz LVPECL Phase Noise.

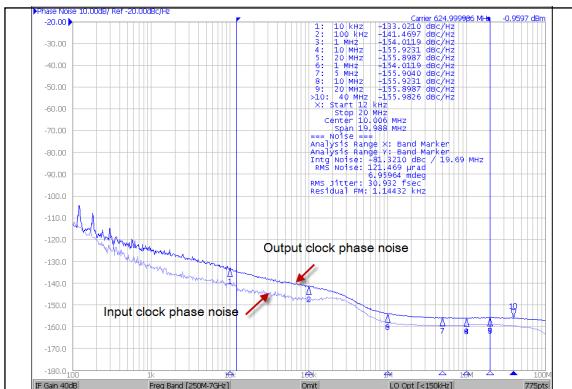


FIGURE 3-14: 625 MHz LVPECL Phase Noise.

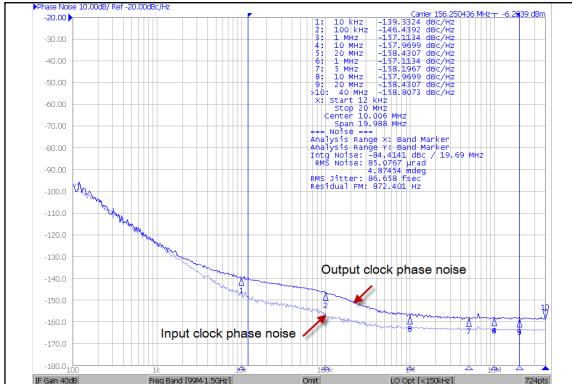


FIGURE 3-15: 156.25 MHz LVDS Phase Noise.

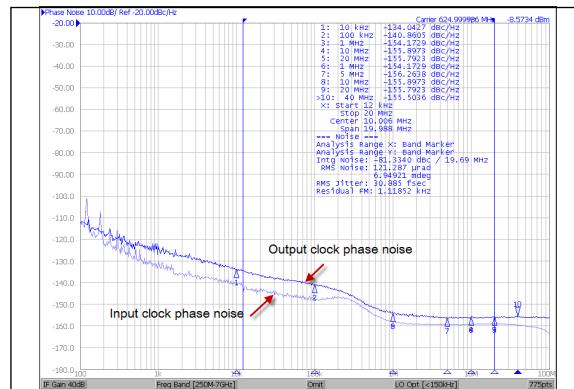


FIGURE 3-16: 625 MHz LVDS Phase Noise.

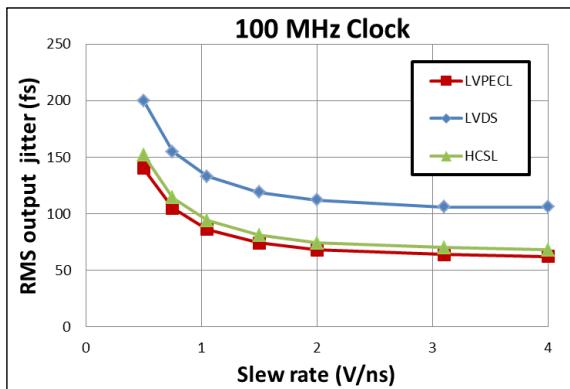


FIGURE 3-17: Output RMS Jitter (12 kHz to 20 MHz) vs. Input Clock Slew Rate.

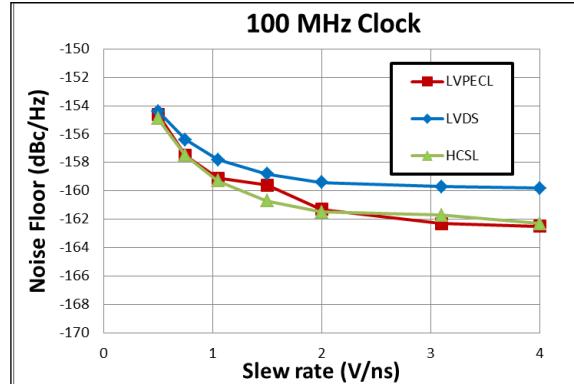


FIGURE 3-18: Output Clock Noise Floor vs. Input Clock Slew Rate.

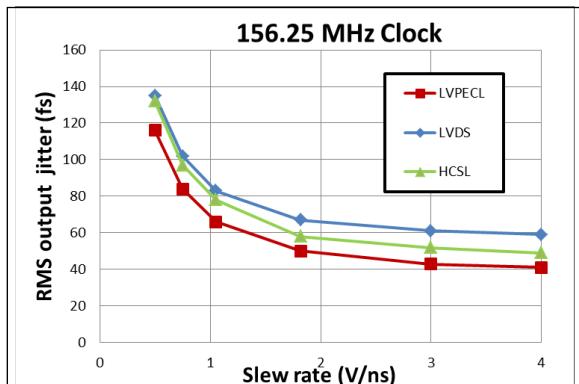


FIGURE 3-19: Output RMS Jitter (12 kHz to 20 MHz) vs. Input Clock Slew Rate.

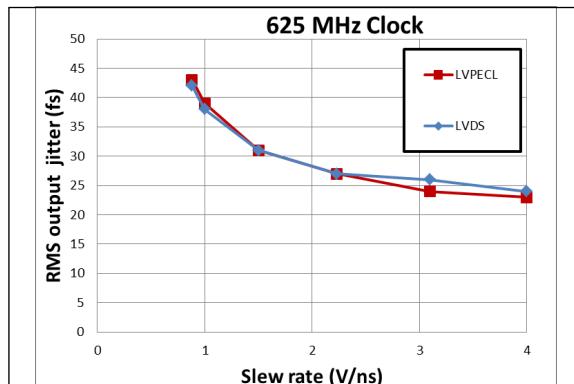


FIGURE 3-21: Output RMS Jitter (12 kHz to 20 MHz) vs. Input Clock Slew Rate.

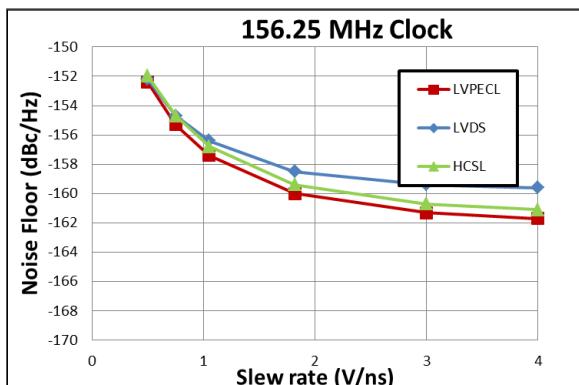


FIGURE 3-20: Output Clock Noise Floor vs. Input Clock Slew Rate.

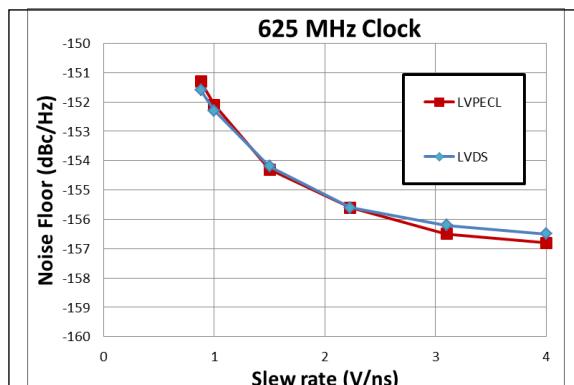


FIGURE 3-22: Output Clock Noise Floor vs. Input Clock Slew Rate.

4.0 ELECTRICAL CHARACTERISTICS

TABLE 4-1: ABSOLUTE MAXIMUM RATINGS

| (Note 1, Note 2, Note 3) | | | | |
|---------------------------|------------------|------|------|-------|
| Parameter | Symbol | Min. | Max. | Units |
| Supply Voltage, 3.3V | V_{DD}/V_{DDO} | -0.5 | 4.6 | V |
| Supply Voltage, 2.5V | V_{DD}/V_{DDO} | -0.5 | 3.5 | V |
| Storage Temperature Range | T_{ST} | -55 | 125 | °C |

Note 1: Exceeding these values may cause permanent damage.

2: Functional operation under these conditions is not implied.

3: Voltages are with respect to ground (GND) unless otherwise stated.

TABLE 4-2: RECOMMENDED OPERATING CONDITIONS

| (Note 1, Note 2) | | | | | |
|-----------------------|----------------------------------|-------|------|----------------|-------|
| Parameter | Symbol | Min. | Typ. | Max. | Units |
| Supply Voltage, 3.3V | $V_{DD}/V_{DDO}/V_{DD_LVC MOS}$ | 3.135 | 3.30 | 3.465 | V |
| Supply Voltage, 2.5V | $V_{DD}/V_{DDO}/V_{DD_LVC MOS}$ | 2.375 | 2.50 | 2.625 | V |
| Supply Voltage, 1.8V | $V_{DD_LVC MOS}$ | 1.6 | 1.8 | 2.0 | V |
| Supply Voltage, 1.5V | $V_{DD_LVC MOS}$ | 1.35 | 1.5 | 1.65 | V |
| Operating Temperature | T_A | -40 | +25 | +85 | °C |
| Input Voltage | V_{DD-IN} | -0.3 | — | $V_{DD} + 0.3$ | V |

Note 1: Voltages are with respect to ground (GND) unless otherwise stated.

2: The device core supports two power supply modes (3.3V and 2.5V).

TABLE 4-3: CURRENT CONSUMPTION

| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
|--|------------------------|------|-------|-------|-------|--------------------------|
| Core device current (all outputs and XTAL disabled) | $I_{S_3.3V}$ | — | 163 | 197 | mA | $V_{DD} = 3.3V \pm 5\%$ |
| | $I_{S_2.5V}$ | — | 153 | 187 | mA | $V_{DD} = 2.5V \pm 5\%$ |
| Core device current (all outputs disabled) XTAL circuit enabled with 25 MHz Crystal connected between XIN and XOUT | $I_{DD_XTAL_3.3V}$ | — | 128 | 154 | mA | $V_{DD} = 3.3V \pm 5\%$ |
| | $I_{DD_XTAL_2.5V}$ | — | 124 | 150 | mA | $V_{DD} = 2.5V \pm 5\%$ |
| Common output current | $I_{DD_CM_3.3V}$ | — | 13.44 | 15.05 | mA | $V_{DDO} = 3.3V \pm 5\%$ |
| | $I_{DD_CM_2.5V}$ | — | 12.18 | 13.65 | mA | $V_{DDO} = 2.5V \pm 5\%$ |
| Dynamic LVC MOS output current ($f = 100$ MHz) Needs to be scaled for different frequencies by $f/100$ MHz | $I_{DD_3.3V}$ | — | 2.38 | 2.68 | mA | $V_{DDO} = 3.3V \pm 5\%$ |
| | $I_{DD_2.5V}$ | — | 1.74 | 1.96 | mA | $V_{DDO} = 2.5V \pm 5\%$ |
| Current dissipation per LVPECL output | $I_{DD_LVPECL_3.3V}$ | — | 19.36 | 23.26 | mA | $V_{DDO} = 3.3V \pm 5\%$ |
| | $I_{DD_LVPECL_2.5V}$ | — | 19.38 | 22.17 | mA | $V_{DDO} = 2.5V \pm 5\%$ |
| Current dissipation per LVDS output | $I_{DD_LVDS_3.3V}$ | — | 6.73 | 8.00 | mA | $V_{DDO} = 3.3V \pm 5\%$ |
| | $I_{DD_LVDS_2.5V}$ | — | 6.87 | 7.83 | mA | $V_{DDO} = 2.5V \pm 5\%$ |
| Current dissipation per HCSL output | $I_{DD_HCSL_3.3V}$ | — | 16.43 | 19.87 | mA | $V_{DDO} = 3.3V \pm 5\%$ |
| | $I_{DD_HCSL_2.5V}$ | — | 17.14 | 19.18 | mA | $V_{DDO} = 2.5V \pm 5\%$ |

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TABLE 4-4: INPUT CHARACTERISTICS

| Note 1, Note 2, Note 3 | | | | | | |
|--|-----------------|------|------|------|------------|-------------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| CMOS high-level input voltage for control inputs | V_{CIH} | 1.05 | — | — | V | — |
| CMOS low-level input voltage for control inputs | V_{CIL} | — | — | 0.45 | V | — |
| CMOS input leakage current for control inputs (includes current due to pull-down resistors) | I_{IL} | -25 | — | 50 | μA | $V_I = V_{DD}$ or 0V |
| Differential input common mode voltage for IN0_p/n and IN1_p/n | V_{CM} | 1 | — | 2 | V | — |
| Differential input voltage difference for IN0_p/n and IN1_p/n, $f \leq 1$ GHz (Note 4) | V_{ID} | 0.15 | — | 1.3 | V | — |
| Differential input voltage difference for IN0_p/n and IN1_p/n for $1 \text{ GHz} < f \leq 1.6$ GHz (Note 4) | V_{ID} | 0.35 | — | 1.3 | V | — |
| Differential input leakage current for IN0_p/n and IN1_p/n (includes current due to pull-up and pull-down resistors) | I_{IL} | -150 | — | 150 | μA | $V_I = 2V$ or 0V |
| Single-ended input voltage for IN0_p and IN1_p | V_{SI} | -0.3 | — | 2.7 | V | $V_{DD} = 3.3V$ or 2.5V |
| Single-ended input common mode voltage (IN0_p/n and IN1_p/n) | V_{SIC} | 1 | — | 2 | V | $V_{DD} = 3.3V$ or 2.5V |
| Single-ended input voltage swing for IN0_p and IN1_p | V_{SID} | 0.3 | — | 1.3 | V | $V_{DD} = 3.3V$ or 2.5V |
| Input frequency (differential) | f_{IN} | 0 | — | 1600 | MHz | — |
| Input frequency (LVCMOS) | f_{IN_CMOS} | 0 | — | 250 | MHz | — |
| Input duty cycle | dc | 35% | — | 65% | — | — |
| Input slew rate | Slew | — | 2 | — | V/ns | — |
| Input pull-up/ pull-down resistance | R_{PU}/R_{PD} | — | 60 | — | k Ω | — |
| Input pull-down resistance for INx_p | R_{PD} | — | 30 | — | k Ω | — |
| Input multiplexer isolation IN0_p/n to IN1_p/n and vice versa Power on both inputs 0 dBm, $f_{OFFSET} > 50$ kHz | I_{ISO} | — | -84 | — | dBc | $f_{IN} = 100$ MHz |
| | | — | -82 | — | | $f_{IN} = 200$ MHz |
| | | — | -71 | — | | $f_{IN} = 400$ MHz |
| | | — | -67 | — | | $f_{IN} = 800$ MHz |

Note 1: Values are over recommended operating conditions.

- 2:** Values are over all two power supply modes ($V_{DD} = 3.3V$ and $V_{DD} = 2.5V$).
- 3:** Input mux isolation is measured as amplitude of f_{OFFSET} spur in dBc on the output clock phase noise plot.
- 4:** Input differential voltage is calculated as $V_{ID} = V_{IH} - V_{IL}$ where V_{IH} and V_{IL} are input voltage high and low respectively. It should not be confused with $V_{ID} = 2 \times (V_{IH} - V_{IL})$ used in some data sheets. Please refer to Figure 4-1.

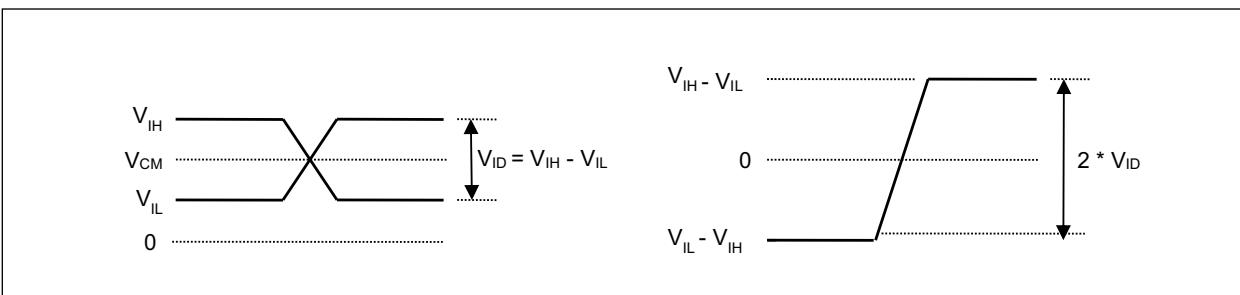


FIGURE 4-1: Differential Input Voltage Levels.

TABLE 4-5: CRYSTAL OSCILLATOR CHARACTERISTICS

| Note 1, Note 2 | | | | | | |
|------------------------------------|-----------------|-------------|------|------|-------|--|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Mode of oscillation | Mode | Fundamental | | | — | — |
| Frequency | f | 8 | — | 160 | MHz | — |
| On chip load capacitance | C _L | — | 1 | — | pF | — |
| On chip series resistor | R _S | — | 0 | — | Ω | — |
| On chip shunt resistor | R | — | 500 | — | kΩ | — |
| Frequency in overdrive mode Note 3 | f _{OV} | 0.1 | — | 250 | MHz | Functional but may not meet AC parameters Minimum depends on AC coupling Capacitor (0.1 μF assumed) |
| Frequency in bypass mode Note 4 | f _{BP} | 0 | — | 250 | MHz | Functional but may not meet AC parameters |

Note 1: Values are over recommended operating conditions.

2: Values are over all two power supply modes ($V_{DD} = 3.3V$ and $V_{DD} = 2.5V$).

3: Maximum input level is 2V.

4: Maximum output level is V_{DD} .

TABLE 4-6: POWER SUPPLY REJECTION RATIO FOR $V_{DD} = V_{DDO} = 3.3V$

| Note 1, Note 2, Note 3 | | | | | | |
|------------------------|------------------------|------|--------|------|-------|-----------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| PSRR for LVPECL output | PSRR _{LVPECL} | — | -71.75 | — | dBc | $f_{IN} = 156.25$ MHz |
| | | | -84.45 | | | $f_{IN} = 312.5$ MHz |
| | | | -82.11 | | | $f_{IN} = 625$ MHz |
| PSRR for LVDS output | PSRR _{LVDS} | — | -95.16 | — | dBc | $f_{IN} = 156.25$ MHz |
| | | | -97.77 | | | $f_{IN} = 312.5$ MHz |
| | | | -79.23 | | | $f_{IN} = 625$ MHz |
| PSRR for HCSL output | PSRR _{HCSL} | — | -77.15 | — | dBc | $f_{IN} = 100$ MHz |
| | | | -76.75 | | | $f_{IN} = 156.25$ MHz |
| | | | -80.44 | | | $f_{IN} = 312.5$ MHz |

Note 1: Values are over recommended operating conditions.

2: Noise injected to VDDO power supply with frequency 100 kHz and amplitude 100 mVpp.

3: PSRR is measured as amplitude of 100 kHz spur in dBc on the output clock phase noise plot.

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TABLE 4-7: POWER SUPPLY REJECTION RATIO FOR $V_{DD} = V_{DDO} = 2.5V$

| Note 1, Note 2, Note 3 | | | | | | |
|------------------------|-----------------|------|--------|------|-------|-------------------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| PSRR for LVPECL output | $PSRR_{LVPECL}$ | — | —73.68 | — | dBc | $f_{IN} = 156.25 \text{ MHz}$ |
| | | | —78.88 | | | $f_{IN} = 312.5 \text{ MHz}$ |
| | | | —71.82 | | | $f_{IN} = 625 \text{ MHz}$ |
| PSRR for LVDS output | $PSRR_{LVDS}$ | — | —90.04 | — | dBc | $f_{IN} = 156.25 \text{ MHz}$ |
| | | | —79.99 | | | $f_{IN} = 312.5 \text{ MHz}$ |
| | | | —73.45 | | | $f_{IN} = 625 \text{ MHz}$ |
| PSRR for HCSL output | $PSRR_{HCSL}$ | — | —92.16 | — | dBc | $f_{IN} = 100 \text{ MHz}$ |
| | | | —74.08 | | | $f_{IN} = 156.25 \text{ MHz}$ |
| | | | —91.88 | | | $f_{IN} = 312.5 \text{ MHz}$ |

Note 1: Values are over recommended operating conditions.

2: Noise injected to V_{DDO} power supply with frequency 100 kHz and amplitude 100 mVpp.

3: PSRR is measured as amplitude of 100 kHz spur in dBc on the output clock phase noise plot.

TABLE 4-8: LVC MOS OUTPUT CHARACTERISTICS FOR $V_{DDO} = 3.3V$

| Note 1 | | | | | | |
|---|-------------------|-----------------|------|------|----------|------------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage (1 mA load) | V_{OH} | $V_{DDO} - 0.1$ | — | — | V | DC measurement |
| Output low voltage (1 mA load) | V_{OL} | — | — | 0.1 | V | DC measurement |
| Output High Current (Load adjusted to $V_{OUT} = V_{DDO}/2$) | I_{OH} | — | 30 | — | mA | DC measurement |
| Output Low Current (Load adjusted to $V_{OUT} = V_{DDO}/2$) | I_{OL} | — | 34 | — | mA | DC measurement |
| Output impedance | R_O | — | 15 | — | Ω | DC measurement |
| Rise time (20% to 80%) | t_R | — | 220 | 310 | ps | — |
| Fall time (20% to 80%) | t_F | — | 320 | 365 | ps | — |
| Output frequency | f_O | 0 | — | 250 | MHz | — |
| Input to output delay | t_{IOD} | 1.07 | 1.28 | 2.07 | ns | — |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive RMS jitter in 1 MHz to 5 MHz band | $t_{j_1M_5M}$ | — | 46 | 80 | fs | Input Clock 25 MHz |
| Additive RMS jitter in 12 kHz to 5 MHz band | $t_{j_12K_5M}$ | — | 56 | 90 | fs | Input Clock 25 MHz |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_{j_1M_20M}$ | — | 60 | 79 | fs | Input Clock 125 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_{j_12K_20M}$ | — | 65 | 86 | fs | Input Clock 125 MHz |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_{j_1M_20M}$ | — | 61 | 94 | fs | Input Clock 156.25 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_{j_12K_20M}$ | — | 66 | 100 | fs | Input Clock 156.25 MHz |

TABLE 4-8: LVC MOS OUTPUT CHARACTERISTICS FOR $V_{DDO} = 3.3V$

| | | | | | | |
|-------------|-------|---|------|------|--------|-------------------------|
| Noise Floor | N_F | — | -165 | -162 | dBc/Hz | Input clock: 25 MHz |
| | | — | -160 | -156 | | Input clock: 125 MHz |
| | | — | -158 | -153 | | Input clock: 156.25 MHz |

Note 1: Values are over recommended operating conditions.

TABLE 4-9: LVC MOS OUTPUT CHARACTERISTICS FOR $V_{DDO} = 2.5V$

| Note 1 | | | | | | |
|---|------------------|-----------------|------|------|----------|-------------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage (1 mA load) | V_{OH} | $V_{DDO} - 0.1$ | — | — | V | DC measurement |
| Output low voltage (1 mA load) | V_{OL} | — | — | 0.1 | V | DC measurement |
| Output High Current (Load adjusted to $V_{OUT} = V_{DDO}/2$) | I_{OH} | — | 21 | — | mA | DC measurement |
| Output Low Current (Load adjusted to $V_{OUT} = V_{DDO}/2$) | I_{OL} | — | 25 | — | mA | DC measurement |
| Output impedance | R_O | — | 15 | — | Ω | DC measurement |
| Rise time (20% to 80%) | t_R | — | 225 | 310 | ps | — |
| Fall time (20% to 80%) | t_F | — | 320 | 365 | ps | — |
| Output frequency | f_O | 0 | — | 250 | MHz | — |
| Input to output delay | t_{IOD} | 1.10 | 1.41 | 2.30 | ns | — |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive RMS jitter in 1 MHz to 5 MHz band | $t_j_{1M_5M}$ | — | 51 | 104 | fs | Input Clock 25 MHz |
| Additive RMS jitter in 12 kHz to 5 MHz band | $t_j_{12K_5M}$ | — | 62 | 111 | fs | Input Clock 25 MHz |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_j_{1M_20M}$ | — | 64 | 81 | fs | Input Clock 125 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_j_{12k_20M}$ | — | 70 | 88 | fs | Input Clock 125 MHz |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_j_{1M_20M}$ | — | 62 | 94 | fs | Input Clock 156.25 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_j_{12k_20M}$ | — | 68 | 100 | fs | Input Clock 156.25 MHz |
| Noise Floor | N_F | — | -164 | -161 | dBc/Hz | Input clock: 25 MHz |
| | | — | -159 | -155 | | Input clock: 125 MHz |
| | | — | -158 | -153 | | Input clock: 156.25 MHz |

Note 1: Values are over recommended operating conditions.

TABLE 4-10: LVPECL OUTPUT CHARACTERISTICS FOR $V_{DDO} = 3.3V$

| Note 1 | | | | | | |
|---|-------------------------|------|------|------|--------|-------------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage | V_{LVPECL_OH} | 1.9 | 2.08 | 2.4 | V | DC Measurement |
| Output low voltage | V_{LVPECL_OL} | 1.2 | 1.36 | 1.7 | V | DC Measurement |
| Output differential swing (Note 2) | V_{LVPECL_SW} | 0.6 | 0.72 | 0.9 | V | DC Measurement |
| Variation of V_{LVPECL_SW} for complementary output states | ΔV_{LVPECL_SW} | 0 | 0.02 | 0.07 | V | — |
| Common mode output | V_{CM} | 1.6 | 1.72 | 2.1 | V | — |
| Output frequency when $V_{LVPECL_SW} \geq 0.6V$ | $f_{MAX_0.6VSW}$ | — | — | 800 | MHz | — |
| Output frequency when $V_{LVPECL_SW} \geq 0.4V$ | $f_{MAX_0.4VSW}$ | — | — | 1600 | MHz | — |
| Rise or fall time (20% to 80%) | t_R/t_F | — | 110 | 170 | ps | — |
| Output frequency | f_O | 0 | — | 1600 | MHz | — |
| Output to output skew | t_{OOsk} | — | — | 40 | ps | — |
| Device to device output skew | t_{DOOSk} | — | — | 120 | ps | — |
| Input to output delay | t_{IOD} | 0.73 | 0.87 | 1.1 | ns | — |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_{j_1M_20M}$ | — | 68 | 96 | fs | Input clock: 100 MHz |
| | | — | 50 | 64 | fs | Input clock: 156.25 MHz |
| | | — | 20 | 32 | fs | Input clock: 625 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_{j_12k_20M}$ | — | 71 | 101 | fs | Input clock: 100 MHz |
| | | — | 55 | 70 | fs | Input clock: 156.25 MHz |
| | | — | 25 | 39 | fs | Input clock: 625 MHz |
| Noise floor | N_F | — | -161 | -159 | dBc/Hz | Input clock: 100 MHz |
| | | — | -160 | -155 | dBc/Hz | Input clock: 156.25 MHz |
| | | — | -155 | -151 | dBc/Hz | Input clock: 625 MHz |

Note 1: Values are over recommended operating conditions.

2: Output differential swing is calculated as $V_{SW} = V_{OH} - V_{OL}$. It should not be confused with $V_{SW} = 2 \times (V_{OH} - V_{OL})$ used in some data sheets. Please refer to [Figure 4-2](#).

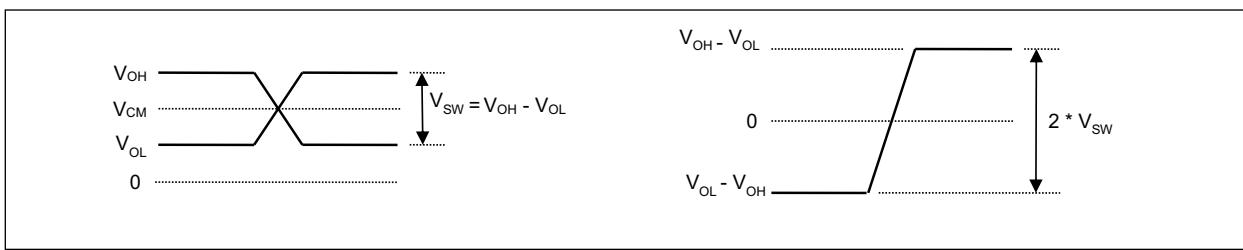


FIGURE 4-2: Differential Output Voltage Levels.

TABLE 4-11: LVPECL OUTPUT CHARACTERISTICS FOR $V_{DDO} = 2.5V$

| Note 1 | | | | | | |
|---|-------------------------|------|------|------|--------|-------------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage | V_{LVPECL_OH} | 1.1 | 1.28 | 1.7 | V | DC Measurement |
| Output low voltage | V_{LVPECL_OL} | 0.4 | 0.57 | 0.9 | V | DC Measurement |
| Output differential swing (Note 2) | V_{LVPECL_SW} | 0.6 | 0.71 | 0.9 | V | DC Measurement |
| Variation of V_{LVPECL_SW} for complementary output states | ΔV_{LVPECL_SW} | 0 | 0.02 | 0.05 | V | — |
| Common mode output | V_{CM} | 0.8 | 0.92 | 1.2 | V | — |
| Output frequency when $V_{LVPECL_SW} \geq 0.6V$ | $f_{MAX_0.6VSW}$ | — | — | 800 | MHz | — |
| Output frequency when $V_{LVPECL_SW} \geq 0.4V$ | $f_{MAX_0.4VSW}$ | — | — | 1600 | MHz | — |
| Rise or fall time (20% to 80%) | t_R/t_F | — | 120 | 170 | ps | — |
| Output frequency | f_O | — | — | 1600 | MHz | — |
| Output to output skew | t_{OOsk} | — | — | 40 | ps | — |
| Device to device output skew | t_{DOOSk} | — | — | 120 | ps | — |
| Input to output delay | t_{IOD} | 0.75 | 0.87 | 1.1 | ns | — |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_{J_1M_20M}$ | — | 65 | 91 | fs | Input clock: 100 MHz |
| | | — | 50 | 64 | fs | Input clock: 156.25 MHz |
| | | — | 20 | 30 | fs | Input clock: 625 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_{J_12k_20M}$ | — | 69 | 99 | fs | Input clock: 100 MHz |
| | | — | 54 | 75 | fs | Input clock: 156.25 MHz |
| | | — | 26 | 41 | fs | Input clock: 625 MHz |
| Noise floor | N_F | — | -161 | -159 | dBc/Hz | Input clock: 100 MHz |
| | | — | -160 | -156 | dBc/Hz | Input clock: 156.25 MHz |
| | | — | -155 | -151 | dBc/Hz | Input clock: 625 MHz |

Note 1: Values are over recommended operating conditions.

2: Output differential swing is calculated as $V_{SW} = V_{OH} - V_{OL}$. It should not be confused with $V_{SW} = 2 \times (V_{OH} - V_{OL})$ used in some data sheets. Please refer to [Figure 4-2](#).

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TABLE 4-12: LVDS OUTPUTS FOR $V_{DDO} = 3.3V$

| Note 1 | | | | | | |
|---|-----------------------|------|-------|------|--------|-------------------------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage | V_{LVDS_OH} | 1.3 | 1.39 | 1.47 | V | DC Measurement |
| Output low voltage | V_{LVDS_OL} | 1.0 | 1.07 | 1.15 | V | DC Measurement |
| Output differential swing (Note 2) | V_{LVDS_SW} | 0.25 | 0.32 | 0.39 | V | DC Measurement |
| Variation of V_{LVDS_SW} for complementary output states | ΔV_{LVDS_SW} | 0 | 0.002 | 0.01 | V | — |
| Common mode output | V_{CM} | 1.15 | 1.23 | 1.3 | V | — |
| Variation of V_{CM} for complementary output states | ΔV_{CM} | 0 | 0.001 | 0.01 | V | — |
| Output frequency when $V_{LVDS_SW} \geq 250$ mV | $f_{MAX_0.25VSW}$ | — | — | 800 | MHz | — |
| Output frequency when $V_{LVDS_SW} \geq 200$ mV | $f_{MAX_0.2VSW}$ | — | — | 1600 | MHz | — |
| Rise or fall time (20% to 80%) | t_R/t_F | — | 110 | 170 | ps | — |
| Output frequency | f_O | 0 | — | 1600 | MHz | — |
| Output to output skew | t_{OOsk} | — | — | 20 | ps | — |
| Device to device output skew | t_{DOOSk} | — | — | 130 | ps | — |
| Input to output delay | t_{IOD} | 0.76 | 0.86 | 1.1 | ns | — |
| Output Short Circuit Current Single-Ended | I_S | -24 | — | 24 | mA | Single-ended outputs shorted to GND |
| Output Short Circuit Current Differential | I_{SD} | -24 | — | 24 | mA | Complementary outputs shorted |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_{j_1M_20M}$ | — | 110 | 144 | fs | Input clock: 100 MHz |
| | | — | 63 | 81 | fs | Input clock: 156.25 MHz |
| | | — | 21 | 33 | fs | Input clock: 625 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_{j_12k_20M}$ | — | 115 | 150 | fs | Input clock: 100 MHz |
| | | — | 73 | 102 | fs | Input clock: 156.25 MHz |
| | | — | 26 | 40 | fs | Input clock: 625 MHz |
| Noise floor | N_F | — | -158 | -156 | fs | Input clock: 100 MHz |
| | | — | -158 | -155 | fs | Input clock: 156.25 MHz |
| | | — | -154 | -151 | fs | Input clock: 625 MHz |

Note 1: Values are over recommended operating conditions.

2: Output differential swing is calculated as $V_{SW} = V_{OH} - V_{OL}$. It should not be confused with $V_{SW} = 2 \times (V_{OH} - V_{OL})$ used in some data sheets. Please refer to [Figure 4-2](#).

TABLE 4-13: LVDS OUTPUTS FOR $V_{DDO} = 2.5V$

| Note 1 | | | | | | |
|---|-----------------------|------|-------|------|-------|----------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage | V_{LVDS_OH} | 1.3 | 1.4 | 1.5 | V | DC Measurement |
| Output low voltage | V_{LVDS_OL} | 0.97 | 1.05 | 1.13 | V | DC Measurement |
| Output differential swing (Note 2) | V_{LVDS_SW} | 0.25 | 0.35 | 0.44 | V | DC Measurement |
| Variation of V_{LVDS_SW} for complementary output states | ΔV_{LVDS_SW} | 0 | 0.001 | 0.01 | V | — |

TABLE 4-13: LVDS OUTPUTS FOR $V_{DDO} = 2.5V$ (CONTINUED)

| | | | | | | |
|---|--------------------|------|-------|------|--------|-------------------------------------|
| Common mode output | V_{CM} | 1.15 | 1.23 | 1.3 | V | — |
| Variation of V_{CM} for complementary output states | ΔV_{CM} | 0 | 0.001 | 0.01 | V | — |
| Output frequency when $V_{LVDS_SW} \geq 250$ mV | $f_{MAX_0.25VSW}$ | — | — | 800 | MHz | — |
| Output frequency when $V_{LVDS_SW} \geq 200$ mV | $f_{MAX_0.2VSW}$ | — | — | 1600 | MHz | — |
| Rise or fall time (20% to 80%) | t_R/t_F | — | 110 | 170 | ps | — |
| Output frequency | f_O | 0 | — | 1600 | MHz | — |
| Output to output skew | t_{OOSK} | — | — | 20 | ps | — |
| Device to device output skew | t_{DOOSK} | — | — | 130 | ps | — |
| Input to output delay | t_{IOD} | 0.78 | 0.86 | 1.12 | ns | — |
| Output Short Circuit Current Single-Ended | I_S | -24 | — | 24 | mA | Single-ended outputs shorted to GND |
| Output Short Circuit Current Differential | I_{SD} | -24 | — | 24 | mA | Complementary outputs shorted |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_{J_1M_20M}$ | — | 107 | 140 | fs | Input clock: 100 MHz |
| | | — | 62 | 77 | fs | Input clock: 156.25 MHz |
| | | — | 20 | 31 | fs | Input clock: 625 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_{J_12k_20M}$ | — | 111 | 146 | fs | Input clock: 100 MHz |
| | | — | 66 | 83 | fs | Input clock: 156.25 MHz |
| | | — | 24 | 36 | fs | Input clock: 625 MHz |
| Noise floor | N_F | — | -158 | -156 | fs | Input clock: 100 MHz |
| | | — | -159 | -155 | fs | Input clock: 156.25 MHz |
| | | — | -155 | -151 | fs | Input clock: 625 MHz |

Note 1: Values are over recommended operating conditions.

2: Output differential swing is calculated as $V_{SW} = V_{OH} - V_{OL}$. It should not be confused with $V_{SW} = 2 \times (V_{OH} - V_{OL})$ used in some data sheets. Please refer to [Figure 4-2](#).

TABLE 4-14: HCSL OUTPUTS FOR $V_{DDO} = 3.3V$

| Note 1 | | | | | | |
|---|-----------------------|-------|-------|-------|-------|----------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage | V_{HCSL_OH} | 0.6 | 0.85 | 1.1 | V | DC Measurement |
| Output low voltage | V_{HCSL_OL} | -0.05 | 0 | 0.05 | V | DC Measurement |
| Output differential swing (Note 2) | V_{HCSL_SW} | 0.6 | 0.85 | 1.1 | V | DC Measurement |
| Variation of V_{HCSL_SW} for complementary output states | ΔV_{HCSL_SW} | 0 | 0.003 | 0.05 | V | — |
| Common mode output | V_{CM} | 0.28 | 0.43 | 0.55 | V | — |
| Variation of V_{CM} for complementary output states | ΔV_{CM} | 0 | 0.002 | 0.05 | V | — |
| Absolute Crossing Voltage | V_{CROSS} | 0.320 | 0.384 | 0.447 | V | — |
| Total Variation of V_{CROSS} | ΔV_{CROSS} | — | — | 0.127 | V | — |
| Output frequency | f_{MAX} | 0 | — | 400 | MHz | — |
| Rise or fall time (20% to 80%) | t_R/t_F | — | 143 | 309 | ps | — |
| Output to output skew | t_{OOSK} | — | — | 21 | ps | — |

TABLE 4-14: HCSL OUTPUTS FOR $V_{DDO} = 3.3V$ (CONTINUED)

| | | | | | | |
|---|-------------------|------|------|------|--------|-------------------------|
| Device to device output skew | t_{DOOSK} | — | — | 129 | ps | — |
| Input to output delay | t_{IOD} | 0.73 | 0.90 | 1.08 | ns | — |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive Jitter as per PCIe 3.0 (PLL_BW = 2 MHz to 5 MHz, CDR = 10 MHz) | $t_{jPCle_3.0}$ | — | 20 | 40 | fs | Input clock: 100 MHz |
| Additive Jitter as per PCIe 4.0 (PLL_BW = 2 MHz to 5 MHz, CDR = 10 MHz) | $t_{jPCle_4.0}$ | — | 20 | 40 | fs | Input clock: 100 MHz |
| Additive Jitter as per PCIe 5.0 (PLL_BW = 0.5 MHz to 1.8 MHz, CDR for 32 GT/s CC) | $t_{jPCle_5.0}$ | — | 13 | 19 | fs | Input clock: 100 MHz |
| Additive RMS jitter in 1 MHz to 20 MHz band | $t_{j_1M_20M}$ | — | 73 | 104 | fs | Input clock: 100 MHz |
| | | — | 53 | 69 | fs | Input clock: 156.25 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | $t_{j_12k_20M}$ | — | 77 | 112 | fs | Input clock: 100 MHz |
| | | — | 64 | 100 | fs | Input clock: 156.25 MHz |
| Noise floor | N_F | — | -161 | -159 | dBc/Hz | Input clock: 100 MHz |
| | | — | -159 | -155 | dBc/Hz | Input clock: 156.25 MHz |

Note 1: Values are over recommended operating conditions.

2: Output differential swing is calculated as $V_{SW} = V_{OH} - V_{OL}$. It should not be confused with $V_{SW} = 2 \times (V_{OH} - V_{OL})$ used in some data sheets. Please refer to [Figure 4-2](#).

TABLE 4-15: HCSL OUTPUTS FOR $V_{DDO} = 2.5V$

| Note 1 | | | | | | |
|---|-----------------------|-------|-------|-------|--------|----------------------|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Output high voltage | V_{HCSL_OH} | 0.6 | 0.83 | 1.1 | V | DC Measurement |
| Output low voltage | V_{HCSL_OL} | -0.05 | 0 | 0.05 | V | DC Measurement |
| Output differential swing (Note 2) | V_{HCSL_SW} | 0.5 | 0.83 | 1.1 | V | DC Measurement |
| Variation of V_{HCSL_SW} for complementary output states | ΔV_{HCSL_SW} | 0 | 0.003 | 0.05 | V | — |
| Common mode output | V_{CM} | 0.28 | 0.42 | 0.55 | V | — |
| Variation of V_{CM} for complementary output states | ΔV_{CM} | 0 | 0.002 | 0.05 | V | — |
| Absolute Crossing Voltage | V_{CROSS} | 0.260 | 0.316 | 0.372 | V | — |
| Total Variation of V_{CROSS} | ΔV_{CROSS} | — | — | 0.108 | V | — |
| Output frequency | f_{MAX} | 0 | — | 400 | MHz | — |
| Rise or fall time (20% to 80%) | t_R/t_f | — | 125 | 162 | ps | — |
| Output to output skew | t_{OOsk} | — | — | 21 | ps | — |
| Device to device output skew | t_{DOOSK} | — | — | 129 | ps | — |
| Input to output delay | t_{IOD} | 0.76 | 0.92 | 1.10 | ns | — |
| Output enable time | t_{EN} | — | — | 3 | cycles | — |
| Output disable time | t_{DIS} | — | — | 3 | cycles | — |
| Additive Jitter as per PCIe 3.0 (PLL_BW = 2 MHz to 5 MHz, CDR = 10 MHz) | $t_{jPCle_3.0}$ | — | 20 | 40 | fs | Input clock: 100 MHz |

TABLE 4-15: HCSL OUTPUTS FOR V_{DDO} = 2.5V (CONTINUED)

| | | | | | | |
|---|-------------------------|---|------|------|--------|-------------------------|
| Additive Jitter as per PCIe 4.0 (PLL_BW = 2 MHz to 5 MHz, CDR = 10 MHz) | t _j PCIe_4.0 | — | 20 | 40 | fs | Input clock: 100 MHz |
| Additive Jitter as per PCIe 5.0 (PLL_BW = 0.5 MHz to 1.8 MHz, CDR for 32 GT/s CC) | t _j PCIe_5.0 | — | 13 | 19 | fs | Input clock: 100 MHz |
| Additive RMS jitter in 1 MHz to 20 MHz band | t _j _1M_20M | — | 68 | 95 | fs | Input clock: 100 MHz |
| | | — | 52 | 66 | fs | Input clock: 156.25 MHz |
| Additive RMS jitter in 12 kHz to 20 MHz band | t _j _12k_20M | — | 72 | 102 | fs | Input clock: 100 MHz |
| | | — | 56 | 71 | fs | Input clock: 156.25 MHz |
| Noise floor | N _F | — | -161 | -158 | dBc/Hz | Input clock: 100 MHz |
| | | — | -160 | -153 | dBc/Hz | Input clock: 156.25 MHz |

Note 1: Values are over recommended operating conditions.

2: Output differential swing is calculated as $V_{SW} = V_{OH} - V_{OL}$. It should not be confused with $V_{SW} = 2 \times (V_{OH} - V_{OL})$ used in some data sheets. Please refer to [Figure 4-2](#).

TABLE 4-16: LVCMS OUTPUT PHASE NOISE WITH 25 MHZ XTAL

| Note 1 | | | | | | | |
|---------------------------------------|------------------------|------|------|------|--------|---|--|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition | |
| Jitter RMS in 12 kHz to 5 MHz band | t _J _12k_5M | — | 103 | — | fs | $V_{DD} = 3.3V, V_{DDO} = 3.3V$ | |
| | | — | 117 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V$ | |
| Noise floor | N _F | — | -75 | — | dBc/Hz | $V_{DD} = 3.3V, V_{DDO} = 3.3V @ 10 Hz$ | |
| | | — | -107 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @ 100 Hz$ | |
| | | — | -132 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @ 1 kHz$ | |
| | | — | -150 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @ 10 kHz$ | |
| | | — | -162 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @ 100 kHz$ | |
| | | — | -166 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @ 1 MHz$ | |
| | | — | -166 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @ 5 MHz$ | |
| | | — | -70 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @ 10 Hz$ | |
| | | — | -102 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @ 100 Hz$ | |
| | | — | -130 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @ 1 kHz$ | |
| | | — | -149 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @ 10 kHz$ | |
| | | — | -161 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @ 100 kHz$ | |
| | | — | -165 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @ 1 MHz$ | |
| | | — | -165 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @ 5 MHz$ | |

Note 1: Values are over recommended operating conditions.

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TABLE 4-17: LVPECL OUTPUT PHASE NOISE WITH 25 MHZ XTAL

| Note 1 | | | | | | |
|------------------------------------|------------------|------|------|------|--------|--|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Jitter RMS in 12 kHz to 5 MHz band | $t_{J_12k_5M}$ | — | 265 | — | fs | $V_{DD} = 3.3V, V_{DDO} = 3.3V$ |
| | | — | 213 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V$ |
| Noise floor | N_F | — | -75 | — | dBc/Hz | $V_{DD} = 3.3V, V_{DDO} = 3.3V @10 Hz$ |
| | | — | -107 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @100 Hz$ |
| | | — | -133 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @1 kHz$ |
| | | — | -152 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @10 kHz$ |
| | | — | -157 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @100 kHz$ |
| | | — | -158 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @1 MHz$ |
| | | — | -157 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @5 MHz$ |
| | | — | -71 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @10 Hz$ |
| | | — | -103 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @100 Hz$ |
| | | — | -130 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @1 kHz$ |
| | | — | -151 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @10 kHz$ |
| | | — | -158 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @100 kHz$ |
| | | — | -160 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @1 MHz$ |
| | | — | -159 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @5 MHz$ |

Note 1: Values are over recommended operating conditions.

TABLE 4-18: LVDS OUTPUT PHASE NOISE WITH 25 MHZ XTAL

| Note 1 | | | | | | |
|------------------------------------|------------------|------|------|------|--------|--|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Jitter RMS in 12 kHz to 5 MHz band | $t_{J_12k_5M}$ | — | 178 | — | fs | $V_{DD} = 3.3V, V_{DDO} = 3.3V$ |
| | | — | 190 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V$ |
| Noise floor | N_F | — | -75 | — | dBc/Hz | $V_{DD} = 3.3V, V_{DDO} = 3.3V @10 Hz$ |
| | | — | -107 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @100 Hz$ |
| | | — | -133 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @1 kHz$ |
| | | — | -154 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @10 kHz$ |
| | | — | -161 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @100 kHz$ |
| | | — | -161 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @1 MHz$ |
| | | — | -160 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @5 MHz$ |
| | | — | -68 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @10 Hz$ |
| | | — | -103 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @100 Hz$ |
| | | — | -130 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @1 kHz$ |
| | | — | -152 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @10 kHz$ |
| | | — | -161 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @100 kHz$ |
| | | — | -160 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @1 MHz$ |
| | | — | -159 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @5 MHz$ |

Note 1: Values are over recommended operating conditions.

TABLE 4-19: HCSL OUTPUT PHASE NOISE WITH 25 MHZ XTAL

| Note 1 | | | | | | |
|------------------------------------|------------------|------|------|------|--------|--|
| Parameter | Symbol | Min. | Typ. | Max. | Units | Condition |
| Jitter RMS in 12 kHz to 5 MHz band | $t_{J_12k_5M}$ | — | 269 | — | fs | $V_{DD} = 3.3V, V_{DDO} = 3.3V$ |
| | | — | 228 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V$ |
| Noise floor | N_F | — | -76 | — | dBc/Hz | $V_{DD} = 3.3V, V_{DDO} = 3.3V @10 Hz$ |
| | | — | -107 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @100 Hz$ |
| | | — | -133 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @1 kHz$ |
| | | — | -152 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @10 kHz$ |
| | | — | -157 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @100 kHz$ |
| | | — | -157 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @1 MHz$ |
| | | — | -157 | — | | $V_{DD} = 3.3V, V_{DDO} = 3.3V @5 MHz$ |
| | | — | -73 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @10 Hz$ |
| | | — | -105 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @100 Hz$ |
| | | — | -131 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @1 kHz$ |
| | | — | -151 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @10 kHz$ |
| | | — | -158 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @100 kHz$ |
| | | — | -159 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @1 MHz$ |
| | | — | -159 | — | | $V_{DD} = 2.5V, V_{DDO} = 2.5V @5 MHz$ |

Note 1: Values are over recommended operating conditions.

THERMAL SPECIFICATIONS

| Parameter | Symbol | Condition | Value | Units |
|---|---------------|-----------------|-------|-------|
| Maximum Ambient Temperature | T_A | — | 85 | °C |
| Maximum Junction Temperature | $T_{J(MAX)}$ | — | 125 | °C |
| Package Thermal Resistance, 7x7 VQFN 48-Lead | | | | |
| Junction to Ambient Thermal Resistance Note 1 | θ_{JA} | Still air | 21.1 | °C/W |
| | | 1m/s airflow | 16.6 | °C/W |
| | | 2.5 m/s airflow | 15.0 | °C/W |
| Junction to Board Thermal Resistance | θ_{JB} | — | 6.9 | °C/W |
| Junction to Case Thermal Resistance | θ_{JC} | — | 12.8 | °C/W |
| Junction to Pad Thermal Resistance Note 2 | θ_{JP} | Still air | 3.9 | °C/W |
| Junction to Top-Center Thermal Characterization Parameter | Ψ_{JT} | Still air | 0.2 | °C/W |

Note 1: Theta-JA (θ_{JA}) is the thermal resistance from junction to ambient when the package is mounted on an 4-layer JEDEC standard test board and dissipating maximum power.

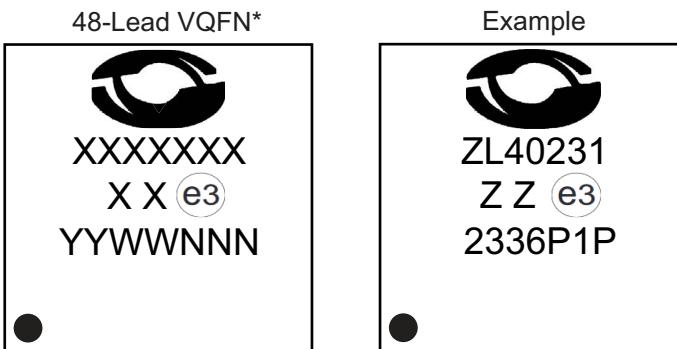
2: Theta-JP (θ_{JP}) is the thermal resistance from junction to the center exposed pad on the bottom of the package).

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NOTES:

5.0 PACKAGE OUTLINE

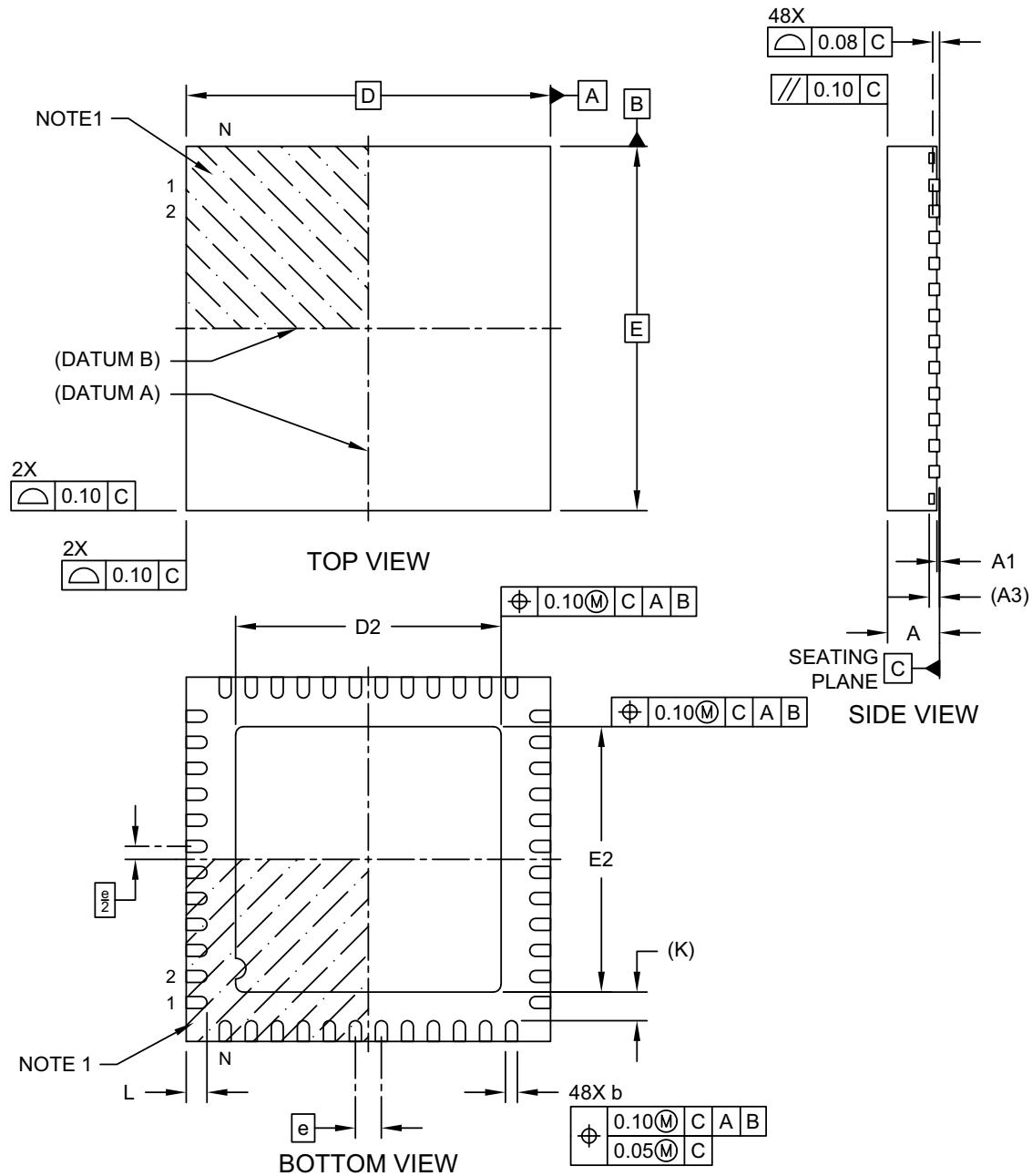
5.1 Package Marking Information



| | |
|----------------|---|
| Legend: | XX...X Product code or customer-specific information Y Year code (last digit of calendar year) YY Year code (last 2 digits of calendar year) WW Week code (week of January 1 is week '01') NNN Alphanumeric traceability code (e3) Pb-free JEDEC® designator for Matte Tin (Sn) * This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package. •, ▲, ▼ Pin one index is identified by a dot, delta up, or delta down (triangle mark). |
| Note: | In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo. Underbar (_) and/or Overbar (¬) symbol may not be to scale. |

**48-Lead Very Thin Plastic Quad Flat, No Lead Package (MAC) - 7x7x1 mm Body [VQFN]
With 5.1 mm Exposed Pad; Microsemi Legacy Package**

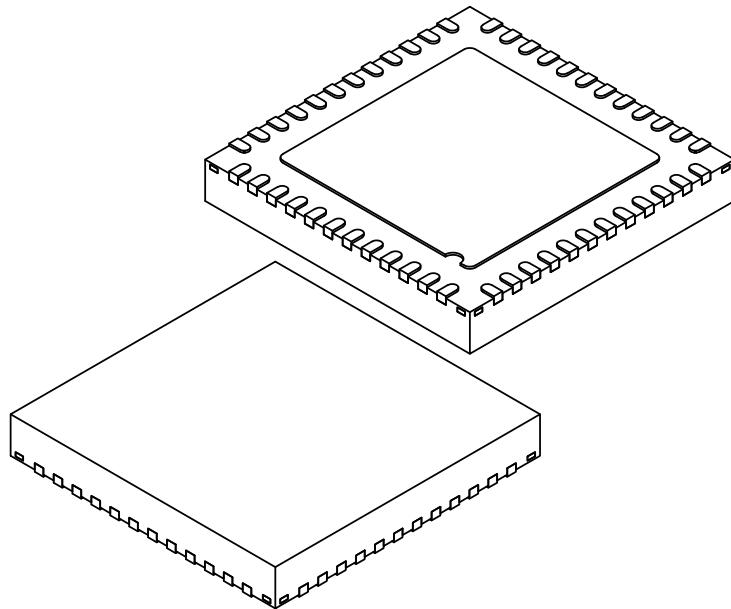
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Microchip Technology Drawing C04-25407 Rev B Sheet 1 of 2

**48-Lead Very Thin Plastic Quad Flat, No Lead Package (MAC) - 7x7x1 mm Body [VQFN]
With 5.1 mm Exposed Pad; Microsemi Legacy Package**

Note: For the most current package drawings, please see the Microchip Packaging Specification located at
<http://www.microchip.com/packaging>



| Dimension | Limits | Units | MILLIMETERS | | |
|-------------------------|--------|-------|-------------|------|------|
| | | | MIN | NOM | MAX |
| Number of Terminals | N | | 48 | | |
| Pitch | e | | 0.50 | BSC | |
| Overall Height | A | | 0.80 | 0.90 | 1.00 |
| Standoff | A1 | | 0.00 | 0.02 | 0.05 |
| Terminal Thickness | A3 | | 0.20 | REF | |
| Overall Length | D | | 7.00 | BSC | |
| Exposed Pad Length | D2 | | 5.00 | 5.10 | 5.20 |
| Overall Width | E | | 7.00 | BSC | |
| Exposed Pad Width | E2 | | 5.00 | 5.10 | 5.20 |
| Terminal Width | b | | 0.16 | 0.23 | 0.30 |
| Terminal Length | L | | 0.35 | 0.40 | 0.45 |
| Terminal-to-Exposed-Pad | K | | 0.55 | REF | |

Notes:

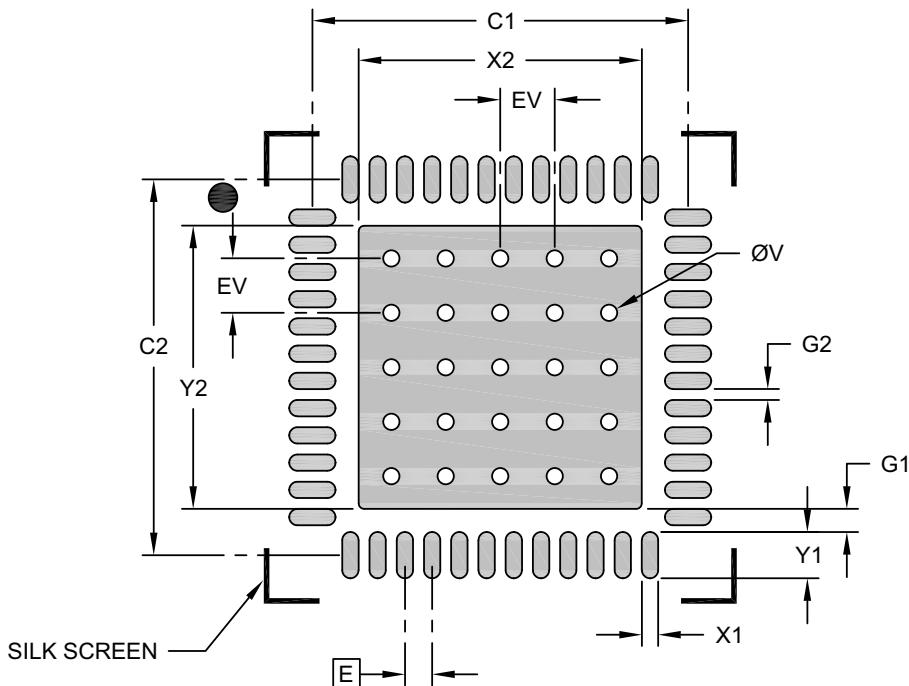
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package is saw singulated
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

48-Lead Very Thin Plastic Quad Flat, No Lead Package (MAC) - 7x7x1 mm Body [VQFN] With 5.1 mm Exposed Pad; Microsemi Legacy Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

| Units | | MILLIMETERS | | |
|----------------------------------|----|-------------|------|------|
| Dimension Limits | | MIN | NOM | MAX |
| Contact Pitch | E | 0.50 BSC | | |
| Optional Center Pad Width | X2 | | | 5.20 |
| Optional Center Pad Length | Y2 | | | 5.20 |
| Contact Pad Spacing | C1 | | 6.90 | |
| Contact Pad Spacing | C2 | | 6.90 | |
| Contact Pad Width (Xnn) | X1 | | | 0.30 |
| Contact Pad Length (Xnn) | Y1 | | | 0.85 |
| Contact Pad to Center Pad (Xnn) | G1 | 0.43 | | |
| Contact Pad to Contact Pad (Xnn) | G2 | 0.20 | | |
| Thermal Via Diameter | V | | 0.30 | |
| Thermal Via Pitch | EV | | 1.00 | |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-27407 Rev B

NOTES:

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APPENDIX A: DATA SHEET REVISION HISTORY

TABLE A-1: REVISION HISTORY

| Revision | Section/Figure/Entry | Correction |
|------------------------|----------------------|---|
| DS20006799A (11-27-23) | — | Converted Microsemi data sheet ZL40231 to Microchip DS20006799A. Minor text changes throughout. |

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

| PART NO. | X | X | X | X | Examples: |
|---------------------------|---|---------|------------|--------|---|
| Device | Chip Carrier Type | Package | Media Type | Finish | |
| Device: | ZL40231: Low Skew, Low Additive Jitter 10 Output LVPECL/LVDS/HCSL Fanout Buffer with One LVCMS Output | | | | a) ZL40231LDG1: ZL40231, Leadless Chip Carrier, 48-Lead VQFN Package, 260/Tray, Pb Free with Matte Sn Lead Finish Equating to RoHS e3 |
| Chip Carrier Type: | L = Leadless Chip Carrier | | | | b) ZL40231LDF1: ZL40231, Leadless Chip Carrier, 48-Lead VQFN Package, 3,000/Reel, Pb Free with Matte Sn Lead Finish Equating to RoHS e3 |
| Package: | D = 48-Lead VQFN Package | | | | |
| Media Type: | G = 260/Tray F = 3,000/Reel | | | | |
| Finish: | 1 = Pb Free with Matte Sn Lead Finish Equating to RoHS e3 | | | | Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option. |

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NOTES:

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